

TPS736 Capacitor-Free, NMOS, 400mA, Low-Dropout Regulator With Reverse Current Protection

1 Features

- Stable with no output capacitor or any value or type of capacitor
- Input voltage range of 1.7V to 5.5V
- Ultra-low dropout voltage: 75mV typ
- Excellent load transient response—with or without optional output capacitor
- NMOS topology delivers low reverse leakage current
- Low noise: $30\mu\text{V}_{\text{RMS}}$ typ (10Hz to 100kHz)
- 0.5% initial accuracy
- 1% overall accuracy over line, load, and temperature
- Less than $1\mu\text{A}$ max I_{Q} in shutdown mode
- Thermal shutdown and specified min/max current limit protection
- Available in multiple output voltage versions:
 - Fixed outputs of 1.20V to 5.0V
 - Adjustable output from 1.20V to 5.5V
 - Custom outputs available

2 Applications

- [Portable-, battery-powered equipment](#)
- Post-regulation for switching supplies
- Noise-sensitive circuitry such as VCOs
- [Point of load regulation for DSPs, FPGAs, ASICs, and microprocessors](#)

3 Description

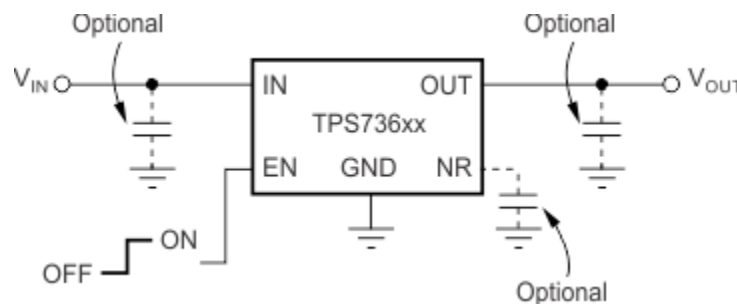
The TPS736 low-dropout (LDO) linear voltage regulator uses a new topology: an NMOS pass transistor in a voltage-follower configuration. This topology is stable using output capacitors with low ESR, and even allows operation without a capacitor. The device also provides high reverse blockage (low reverse current) and ground pin current that is nearly constant over all output current values.

The TPS736 uses an advanced BiCMOS process to yield high precision while delivering very low dropout voltages and low ground pin current. Current consumption, when not enabled, is under $1\mu\text{A}$ and designed for portable applications. The extremely low output noise ($30\mu\text{V}_{\text{RMS}}$ with $0.1\mu\text{F}$ C_{NR}) is designed for powering VCOs. This device is protected by thermal shutdown and foldback current limit.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
TPS736	DBV (SOT-23, 5)	2.9mm × 2.8mm
	DCQ (SOT-223, 6)	6.5mm × 7.06mm
	DRB (VSON, 8)	3mm × 3mm

- (1) For more information, see the [Mechanical, Packaging, and Orderable Information](#).
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.



Typical Application Circuit for Fixed-Voltage Versions

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4 Pin Configuration and Functions

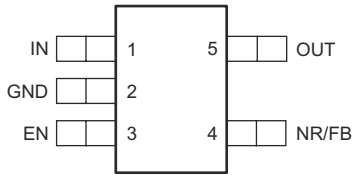


Figure 4-1. DBV Package, 5-Pin SOT-23 (Top View)

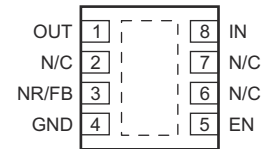


Figure 4-2. DRB Package, 8-Pin VSON (Top View)

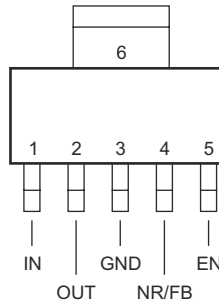


Figure 4-3. DCQ Package, 6-Pin SOT-223 (Top View)

Table 4-1. Pin Functions

NAME	PIN NO.			TYPE ⁽¹⁾	DESCRIPTION
	SOT-23	SOT-223	VSON		
EN	3	5	5	I	Driving the enable pin (EN) high turns on the regulator. Driving this pin low puts the regulator into shutdown mode. See the Enable Pin and Shutdown section for more details. EN can be connected to IN if not used.
FB	4	4	3	I	Adjustable-voltage version only. This pin is the input to the control loop error amplifier, and sets the output voltage of the device.
GND	2	3, 6	4, Pad	—	Ground.
IN	1	1	8	I	Input supply.
NR	4	4	3	—	Fixed-voltage versions only. Connecting an external capacitor to this noise reduction pin bypasses noise generated by the internal band gap, reducing output noise to very low levels.
OUT	5	2	1	O	Output of the regulator. There are no output capacitor requirements for stability.

(1) I = Input; O = Output

5 Specifications

5.1 Absolute Maximum Ratings

over operating junction temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage	Input, V_{IN}	-0.3	6	V
	Enable, V_{EN}	-0.3	6	
	Output, V_{OUT}	-0.3	5.5	
	V_{NR} , V_{FB}	-0.3	6	
Current	Maximum output, I_{OUT}	Internally limited		
Output short-circuit duration		Indefinite		
Continuous total power dissipation	P_{DISS}	See <i>Thermal Information</i>		
Temperature	Operating junction, T_J	-55	150	°C
	Storage, T_{stg}	-65	150	

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±500	

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating junction temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{IN}	Input supply voltage	1.7		5.5	V
I_{OUT}	Output current	0		400	mA
T_J	Operating junction temperature	-40		125	°C

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS736 New silicon			UNIT
		DRB (VSON)	DCQ (SOT-223)	DBV (SOT-23)	
		8 PINS	6 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	49.4	76	185.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	76.6	46.6	82.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	22.0	18.1	53.1	°C/W
ψ_{JT}	Junction-to-top characterization parameter	3.8	8.6	21.1	°C/W
ψ_{JB}	Junction-to-board characterization parameter	22.0	17.6	52.7	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	3.8	N/A	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

5.5 Thermal Information

THERMAL METRIC ^{(1) (2)}		TPS736 Legacy silicon ⁽³⁾			UNIT
		DRB (VSON)	DCQ (SOT-223)	DBV (SOT-23)	
		8 PINS	6 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽⁴⁾	52.8	118.7	221.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance ⁽⁵⁾	60.4	64.9	74.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance ⁽⁶⁾	28.4	65.0	51.9	°C/W
ψ_{JT}	Junction-to-top characterization parameter ⁽⁷⁾	2.1	14.0	2.8	°C/W
ψ_{JB}	Junction-to-board characterization parameter ⁽⁸⁾	28.6	63.8	51.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance ⁽⁹⁾	12.0	N/A	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.
- (2) For thermal estimates of this device based on PCB copper area, see the [TI PCB Thermal Calculator](#).
- (3) Thermal data for the DRB, DCQ, and DBV packages are derived by thermal simulations based on JEDEC-standard methodology as specified in the JESD51 series. The following assumptions are used in the simulations:
 - (a) i. DRB: The exposed pad is connected to the PCB ground layer through a 2×2 thermal via array.
 - ii. DCQ: The exposed pad is connected to the PCB ground layer through a 3×2 thermal via array.
 - iii. DBV: There is no exposed pad with the DBV package.
 - (b) i. DRB: The top and bottom copper layers are assumed to have a 20% thermal conductivity of copper representing a 20% copper coverage.
 - ii. DCQ: Each of top and bottom copper layers has a dedicated pattern for 20% copper coverage.
 - iii. DBV: The top and bottom copper layers are assumed to have a 20% thermal conductivity of copper representing a 20% copper coverage.
 - (c) These data are generated with only a single device at the center of a JEDEC high-K (2s2p) board with 3in × 3in copper area. To understand the effects of the copper area on thermal performance, see the Power Dissipation section of this data sheet.
- (4) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (5) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the top of the package. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (6) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (7) The junction-to-top characterization parameter, ψ_{JT} , estimates the junction temperature of a device in a real system and is extracted from the simulation data to obtain $R_{\theta JA}$ using a procedure described in JESD51-2a (sections 6 and 7).
- (8) The junction-to-board characterization parameter, ψ_{JB} , estimates the junction temperature of a device in a real system and is extracted from the simulation data to obtain $R_{\theta JA}$ using a procedure described in JESD51-2a (sections 6 and 7).
- (9) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

5.6 Electrical Characteristics

Over operating temperature range ($T_J = -40^\circ\text{C}$ to 125°C), $V_{IN} = V_{OUT(nom)} + 0.5V^{(1)}$, $I_{OUT} = 10\text{mA}$, $V_{EN} = 1.7\text{V}$, and $C_{OUT} = 0.1\mu\text{F}$ (unless otherwise noted). Typical values are at $T_J = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{IN}	Input voltage range ^{(1) (2)}			1.7		5.5	V
V_{FB}	Internal reference (TPS73601)	$T_J = 25^\circ\text{C}$		1.198	1.204	1.210	V
V_{OUT}	Output voltage range (TPS73601) ⁽³⁾			V_{FB}		5.5 - V_{DO}	V
	Accuracy ^{(1) (4)}	Nominal	$T_J = 25^\circ\text{C}$	-0.5		0.5	%
		over V_{IN} , I_{OUT} , and T		$V_{OUT} + 0.5V \leq V_{IN} \leq 5.5V$; $10\text{mA} \leq I_{OUT} \leq 400\text{mA}$	-1	± 0.5	
$\Delta V_{OUT(\Delta V_{IN})}$	Line regulation ⁽¹⁾	$V_{OUT(nom)} + 0.5V \leq V_{IN} \leq 5.5V$			0.01		%/V
$\Delta V_{OUT(\Delta I_{OUT})}$	Load regulation	$1\text{mA} \leq I_{OUT} \leq 400\text{mA}$			0.002		%/mA
		$10\text{mA} \leq I_{OUT} \leq 400\text{mA}$			0.0005		
V_{DO}	Dropout voltage ⁽⁵⁾ ($V_{IN} = V_{OUT(nom)} - 0.1V$)	$I_{OUT} = 400\text{mA}$			75	200	mV
$Z_{O(DO)}$	Output impedance in dropout	$1.7V \leq V_{IN} \leq V_{OUT} + V_{DO}$			0.25		Ω
I_{CL}	Output current limit	$V_{OUT} = 0.9 \times V_{OUT(nom)}$	legacy silicon	400	650	800	mA
		$3.6V \leq V_{IN} \leq 4.2V$, $0^\circ\text{C} \leq T_J \leq 70^\circ\text{C}$		500		800	
		$V_{OUT} = 0.9 \times V_{OUT(nom)}$	new silicon	500		800	
I_{SC}	Short-circuit current	$V_{OUT} = 0V$			450		mA
I_{REV}	Reverse leakage current ⁽⁶⁾ ($-I_{IN}$)	$V_{EN} \leq 0.5V$, $0V \leq V_{IN} \leq V_{OUT}$			0.1	10	μA
I_{GND}	Ground pin current	$I_{OUT} = 10\text{mA}$ (I_Q), legacy silicon			400	550	μA
		$I_{OUT} = 10\text{mA}$ (I_Q), new silicon			400	630	
I_{GND}	Ground pin current	$I_{OUT} = 400\text{mA}$			800	1000	μA
I_{SHDN}	Shutdown current (I_{GND})	$V_{EN} \leq 0.5V$, $V_{OUT} \leq V_{IN} \leq 5.5V$, $-40^\circ\text{C} \leq T_J \leq 100^\circ\text{C}$, legacy silicon			0.02	1	μA
		$V_{EN} \leq 0.5V$, $V_{OUT} \leq V_{IN} \leq 5.5V$, new silicon			0.02	1	
I_{FB}	Feedback pin current (TPS73601)				0.1	0.3	μA
PSRR	Power-supply rejection ratio (ripple rejection)	$f = 100\text{Hz}$, $I_{OUT} = 400\text{mA}$			58		dB
		$f = 10\text{kHz}$, $I_{OUT} = 400\text{mA}$			37		
V_N	Output noise voltage, BW = 10Hz to 100kHz	$C_{OUT} = 10\mu\text{F}$, no C_{NR}			$27 \times V_{OUT}$		μV_{RMS}
		$C_{OUT} = 10\mu\text{F}$, $C_{NR} = 0.01\mu\text{F}$			$8.5 \times V_{OUT}$		
t_{STR}	Startup time	$V_{OUT} = 3V$, $R_L = 30\Omega$, $C_{OUT} = 1\mu\text{F}$, $C_{NR} = 0.01\mu\text{F}$			600		μs
$V_{EN(high)}$	EN pin high (enabled)			1.7		V_{IN}	V
$V_{EN(low)}$	EN pin low (shutdown)			0		0.5	V
$I_{EN(high)}$	Enable pin current (enabled)	$V_{EN} = 5.5V$			0.02	0.1	μA
T_{SD}	Thermal shutdown temperature	Shutdown, temperature increasing			160		$^\circ\text{C}$
		Reset, temperature decreasing			140		
T_J	Operating junction temperature			-40		125	$^\circ\text{C}$

- (1) Minimum $V_{IN} = V_{OUT} + V_{DO}$ or 1.7V, whichever is greater.
- (2) For $V_{OUT(nom)} < 1.6V$, when $V_{IN} \leq 1.6V$, the output locks to V_{IN} and can result in a damaging over-voltage condition on the output. To avoid this situation, disable the device before powering down V_{IN} . (Legacy silicon only)
- (3) TPS73601 is tested at $V_{OUT} = 2.5V$.
- (4) Tolerance of external resistors not included in this specification.
- (5) V_{DO} is not measured for output versions with $V_{OUT(nom)} < 1.8V$, because minimum $V_{IN} = 1.7V$.
- (6) Fixed-voltage versions only; refer to *Application Information* section for more information.

5.7 Typical Characteristics

For all voltage versions, at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 0.5\text{V}$, $I_{OUT} = 10\text{mA}$, $V_{EN} = 1.7\text{V}$, and $C_{OUT} = 0.1\mu\text{F}$, unless otherwise noted.

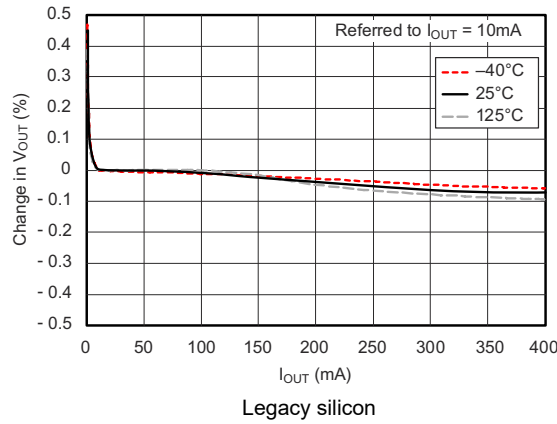


Figure 5-1. Load Regulation

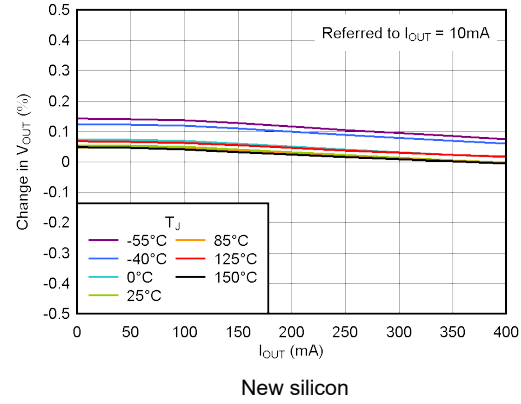


Figure 5-2. Load Regulation

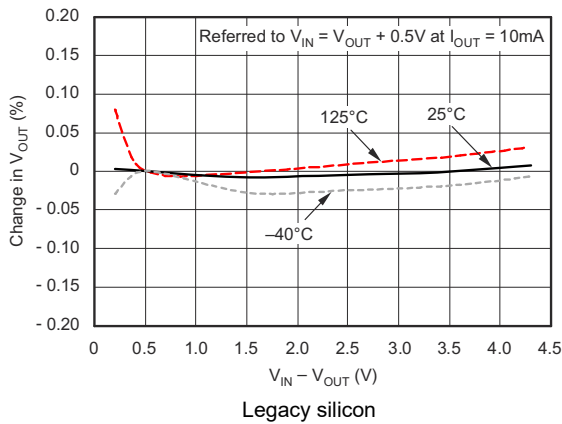


Figure 5-3. Line Regulation

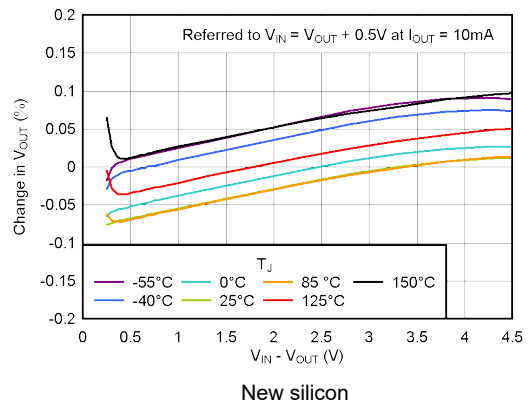


Figure 5-4. Line Regulation

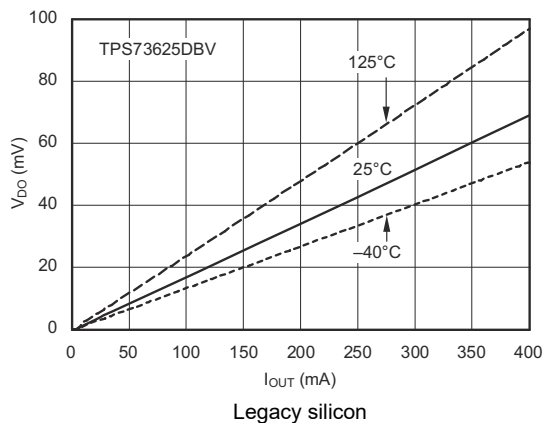


Figure 5-5. Dropout Voltage vs Output Current

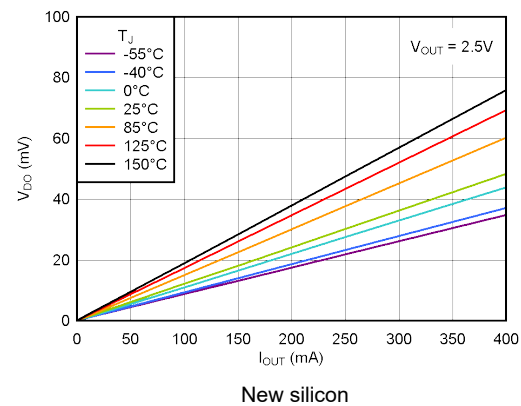


Figure 5-6. Dropout Voltage vs Output Current

5.7 Typical Characteristics (continued)

For all voltage versions, at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 0.5\text{V}$, $I_{OUT} = 10\text{mA}$, $V_{EN} = 1.7\text{V}$, and $C_{OUT} = 0.1\mu\text{F}$, unless otherwise noted.

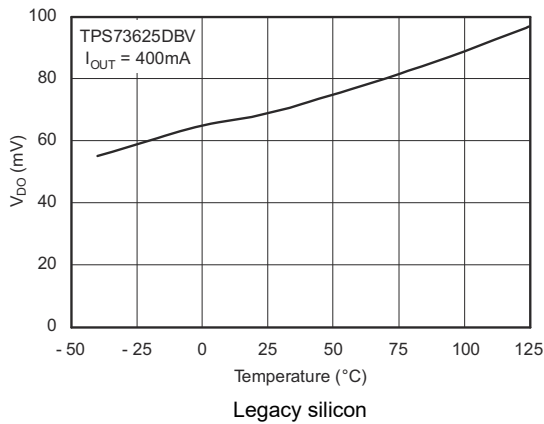


Figure 5-7. Dropout Voltage vs Temperature

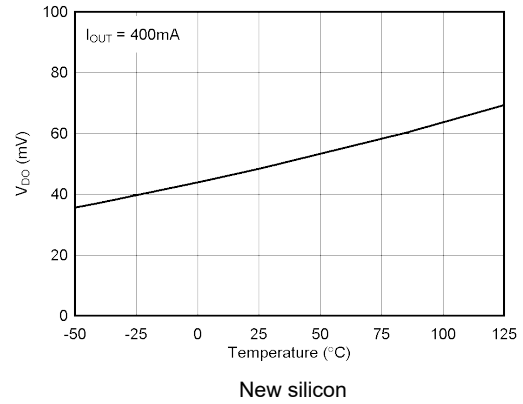


Figure 5-8. Dropout Voltage vs Temperature

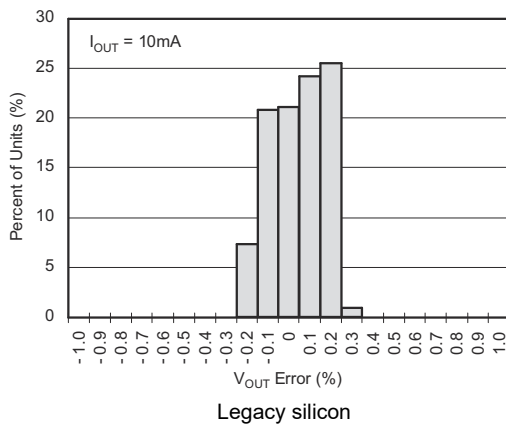


Figure 5-9. Output Voltage Accuracy Histogram

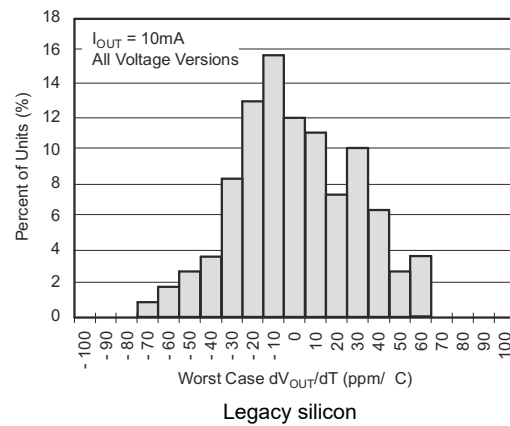


Figure 5-10. Output Voltage Drift Histogram

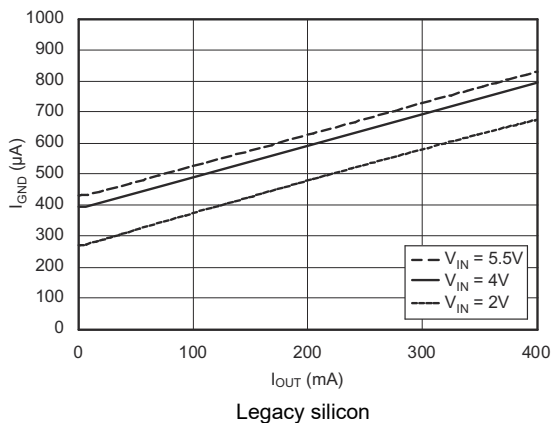


Figure 5-11. Ground Pin Current vs Output Current

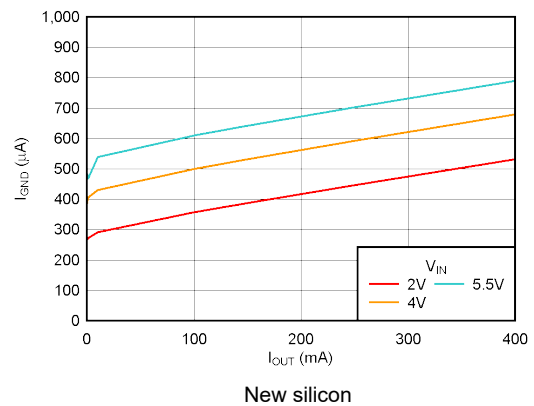


Figure 5-12. Ground Pin Current vs Output Current

5.7 Typical Characteristics (continued)

For all voltage versions, at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 0.5\text{V}$, $I_{OUT} = 10\text{mA}$, $V_{EN} = 1.7\text{V}$, and $C_{OUT} = 0.1\mu\text{F}$, unless otherwise noted.

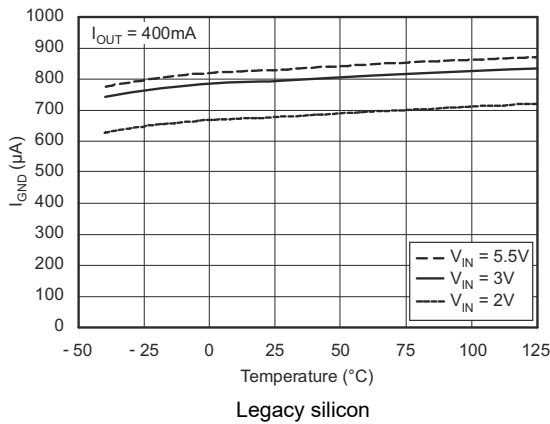


Figure 5-13. Ground Pin Current vs Temperature

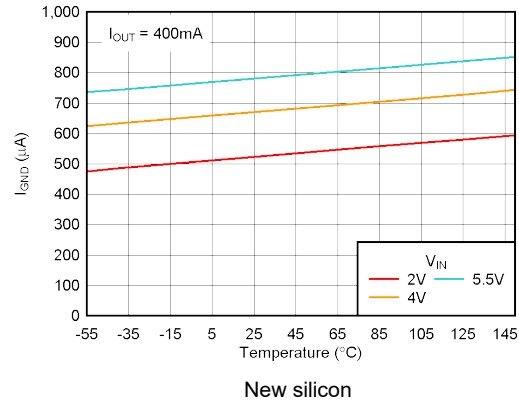


Figure 5-14. Ground Pin Current vs Temperature

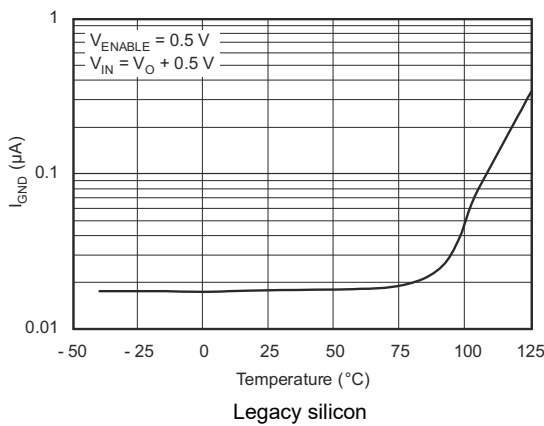


Figure 5-15. Ground Pin Current in Shutdown vs Temperature

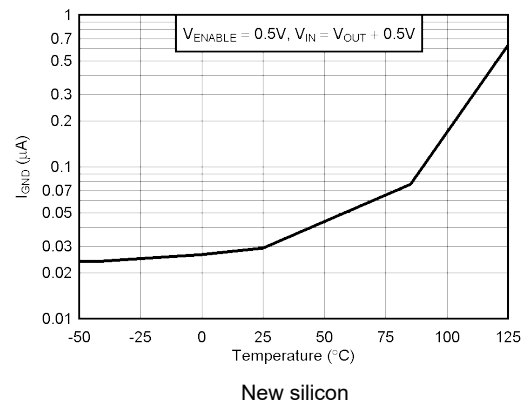


Figure 5-16. Ground Pin Current in Shutdown vs Temperature

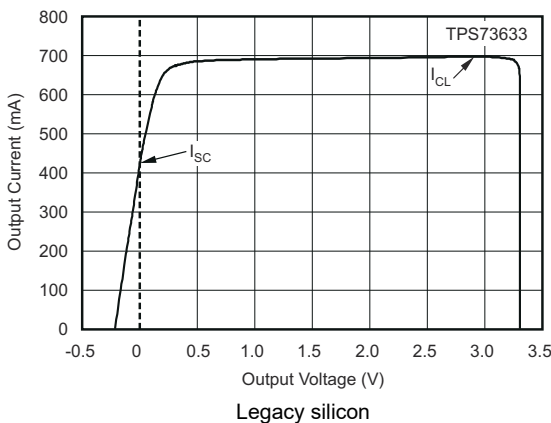


Figure 5-17. Current Limit vs V_{OUT} (Foldback)

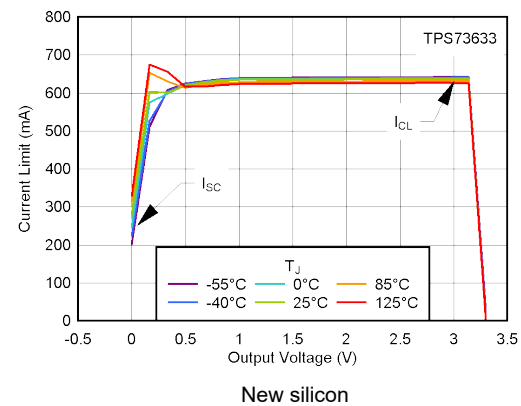


Figure 5-18. Current Limit vs V_{OUT} (Foldback)

5.7 Typical Characteristics (continued)

For all voltage versions, at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 0.5\text{V}$, $I_{OUT} = 10\text{mA}$, $V_{EN} = 1.7\text{V}$, and $C_{OUT} = 0.1\mu\text{F}$, unless otherwise noted.

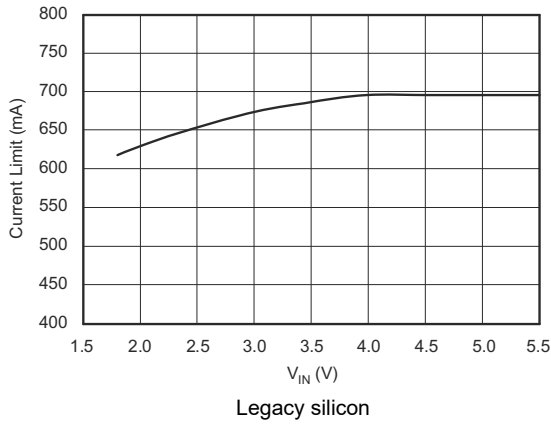


Figure 5-19. Current Limit vs V_{IN}

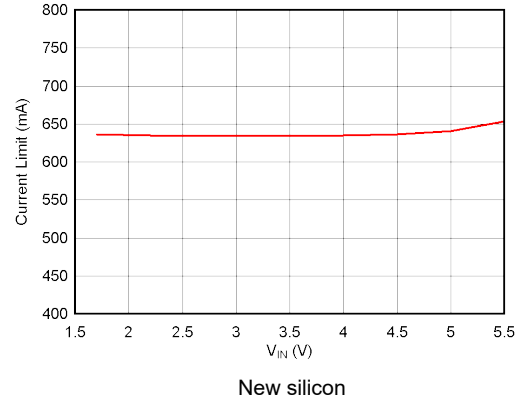


Figure 5-20. Current Limit vs V_{IN}

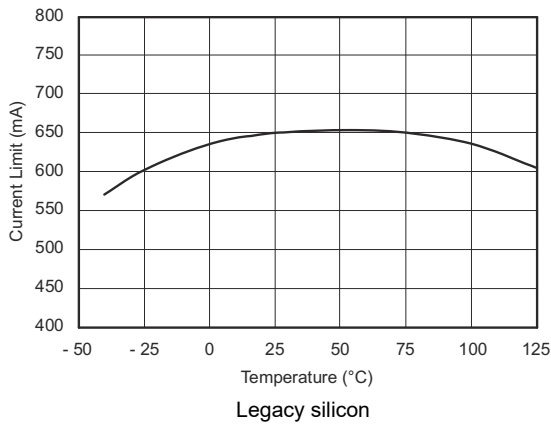


Figure 5-21. Current Limit vs Temperature

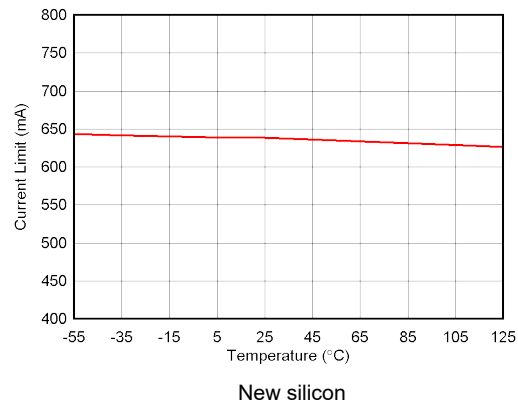


Figure 5-22. Current Limit vs Temperature

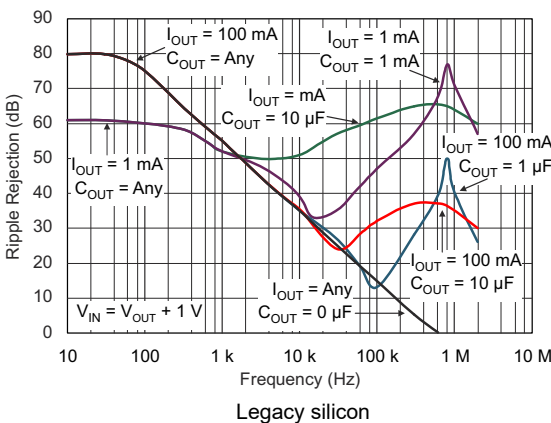


Figure 5-23. PSRR (Ripple Rejection) vs Frequency

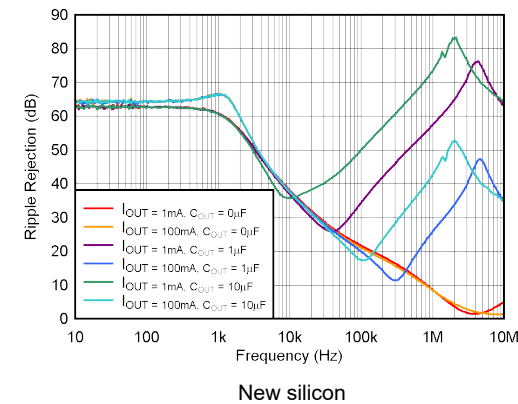


Figure 5-24. PSRR (Ripple Rejection) vs Frequency

5.7 Typical Characteristics (continued)

For all voltage versions, at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 0.5\text{V}$, $I_{OUT} = 10\text{mA}$, $V_{EN} = 1.7\text{V}$, and $C_{OUT} = 0.1\mu\text{F}$, unless otherwise noted.

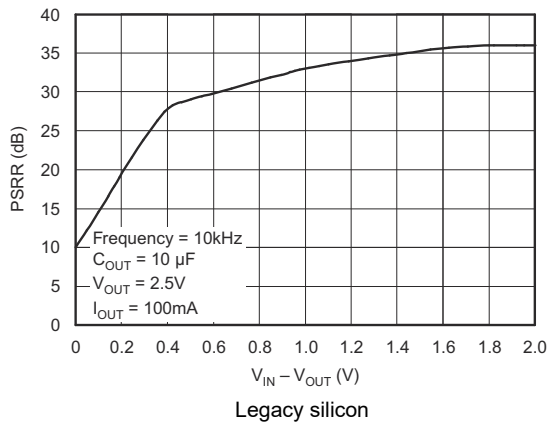


Figure 5-25. PSRR (Ripple Rejection) vs $V_{IN} - V_{OUT}$

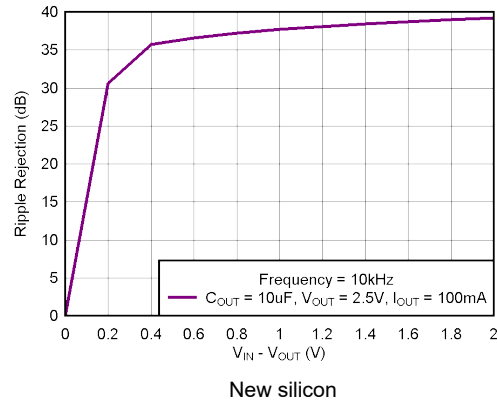


Figure 5-26. PSRR (Ripple Rejection) vs $V_{IN} - V_{OUT}$

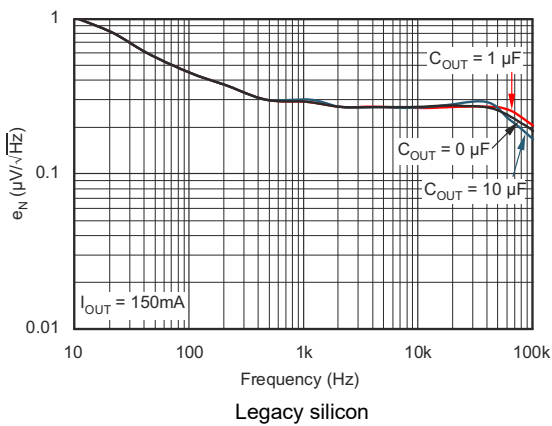


Figure 5-27. Noise Spectral Density $C_{NR} = 0\mu\text{F}$

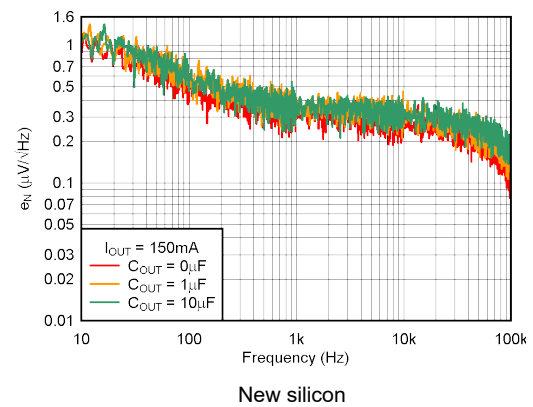


Figure 5-28. Noise Spectral Density $C_{NR} = 0\mu\text{F}$

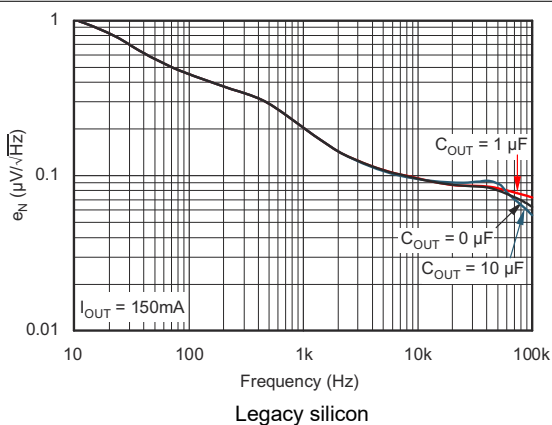


Figure 5-29. Noise Spectral Density $C_{NR} = 0.01\mu\text{F}$

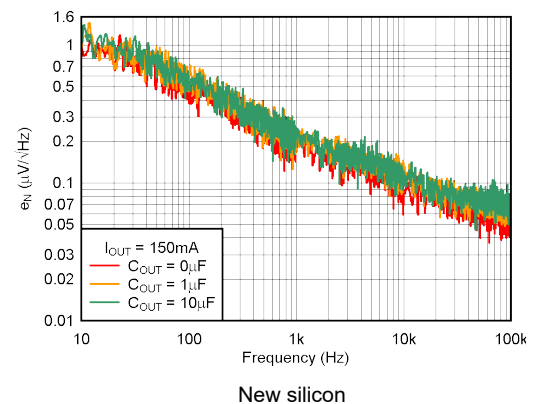


Figure 5-30. Noise Spectral Density $C_{NR} = 0.01\mu\text{F}$

5.7 Typical Characteristics (continued)

For all voltage versions, at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 0.5\text{V}$, $I_{OUT} = 10\text{mA}$, $V_{EN} = 1.7\text{V}$, and $C_{OUT} = 0.1\mu\text{F}$, unless otherwise noted.

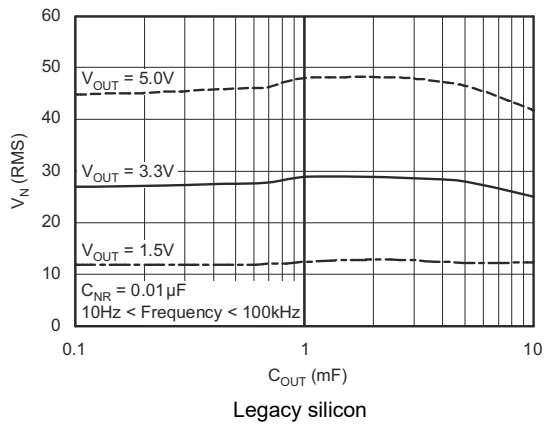


Figure 5-31. RMS Noise Voltage vs C_{OUT}

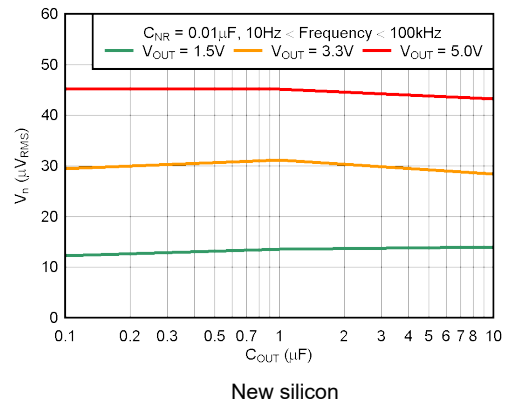


Figure 5-32. RMS Noise Voltage vs C_{OUT}

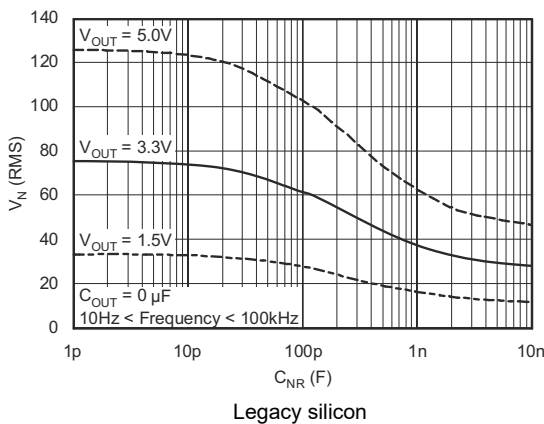


Figure 5-33. RMS Noise Voltage vs C_{NR}

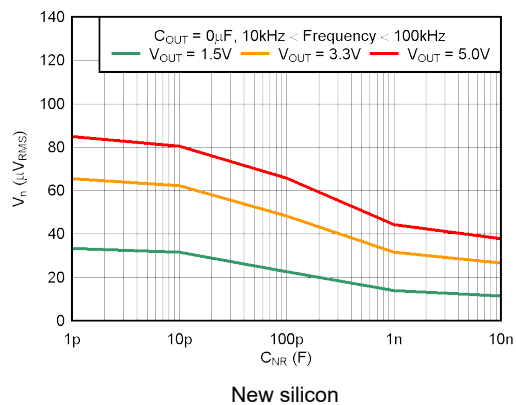


Figure 5-34. RMS Noise Voltage vs C_{NR}

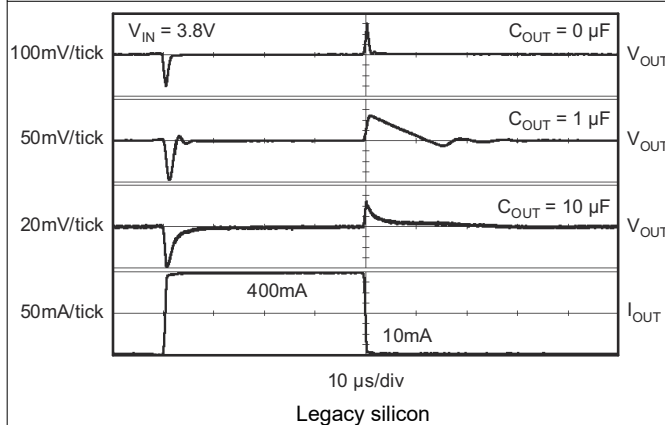


Figure 5-35. TPS73633 Load Transient Response

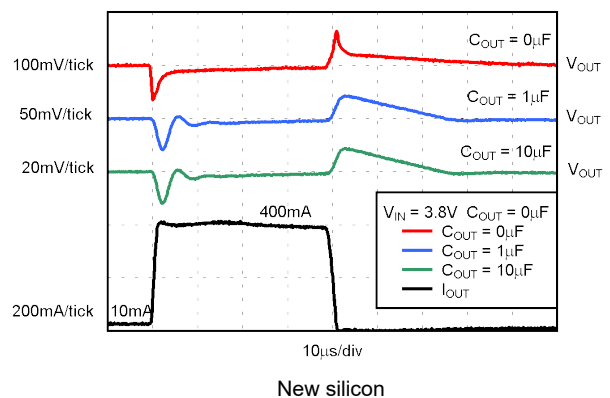


Figure 5-36. TPS73633 Load Transient Response

5.7 Typical Characteristics (continued)

For all voltage versions, at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 0.5\text{V}$, $I_{OUT} = 10\text{mA}$, $V_{EN} = 1.7\text{V}$, and $C_{OUT} = 0.1\mu\text{F}$, unless otherwise noted.

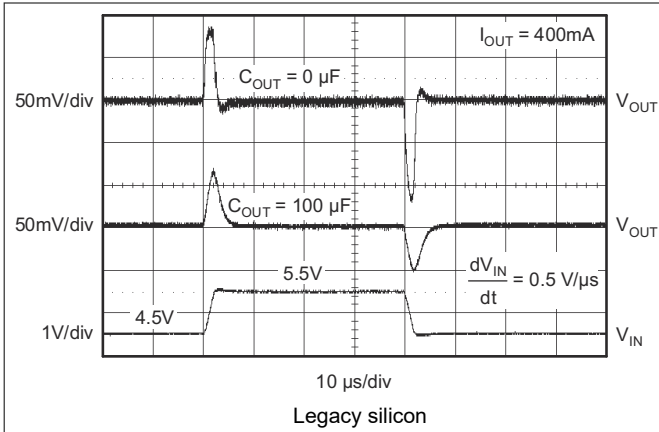


Figure 5-37. TPS73633 Line Transient Response

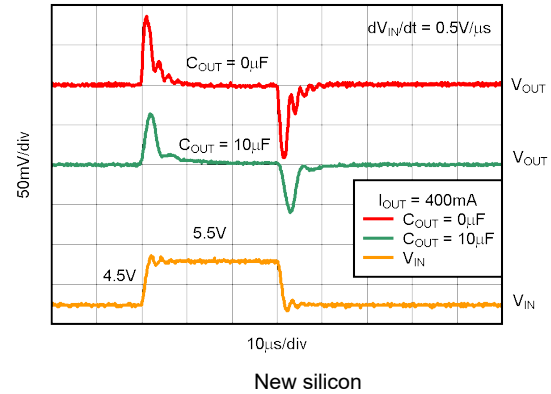


Figure 5-38. TPS73633 Line Transient Response

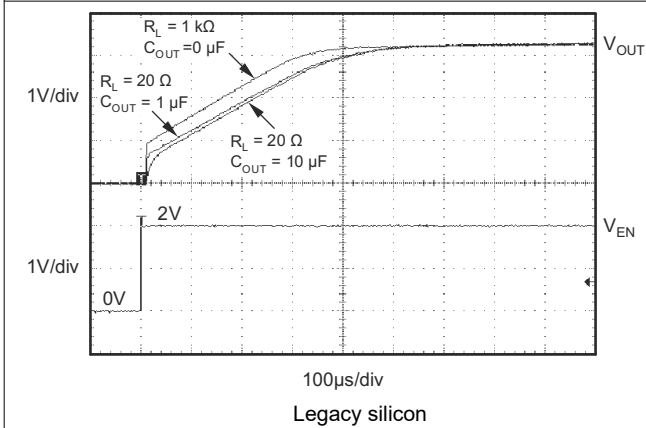


Figure 5-39. TPS73633 Turn-On Response

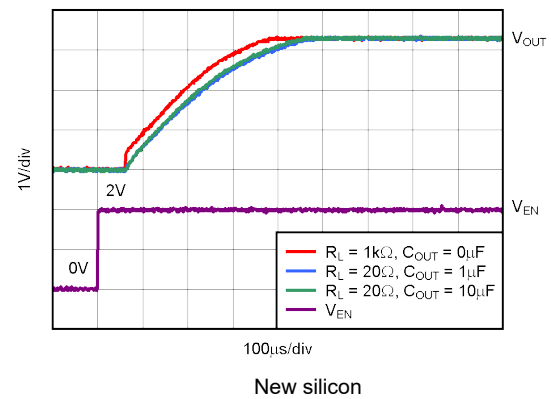


Figure 5-40. TPS73633 Turn-On Response

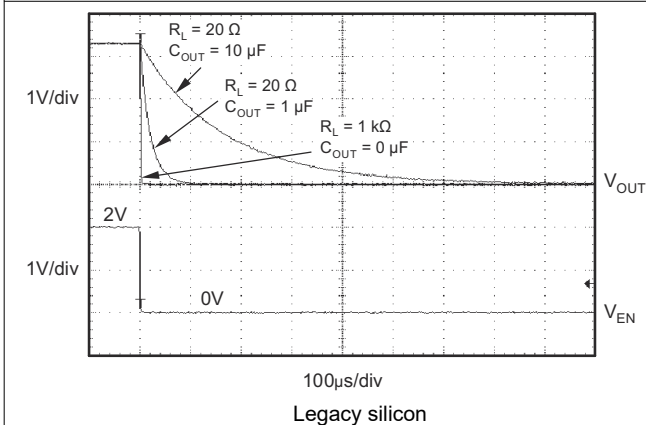


Figure 5-41. TPS73633 Turn-Off Response

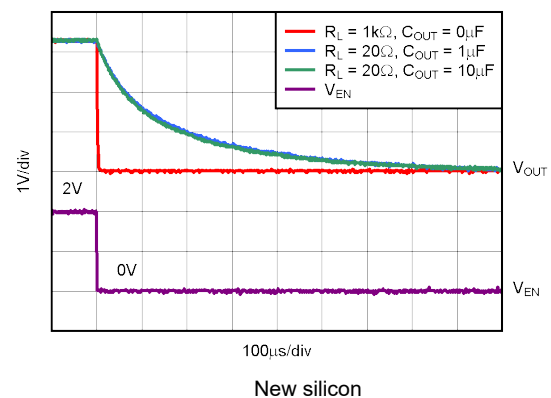


Figure 5-42. TPS73633 Turn-Off Response

5.7 Typical Characteristics (continued)

For all voltage versions, at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 0.5\text{V}$, $I_{OUT} = 10\text{mA}$, $V_{EN} = 1.7\text{V}$, and $C_{OUT} = 0.1\mu\text{F}$, unless otherwise noted.

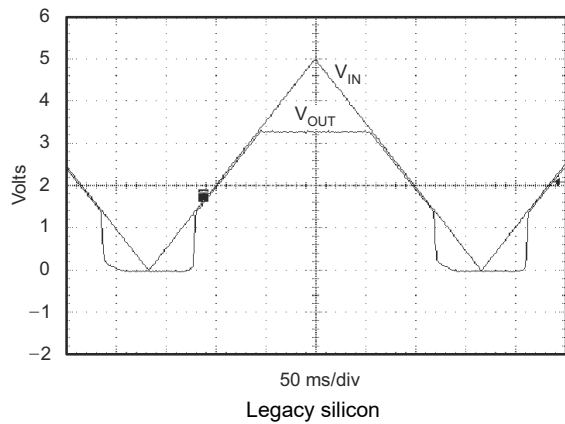


Figure 5-43. TPS73633 Power-Up, Power-Down

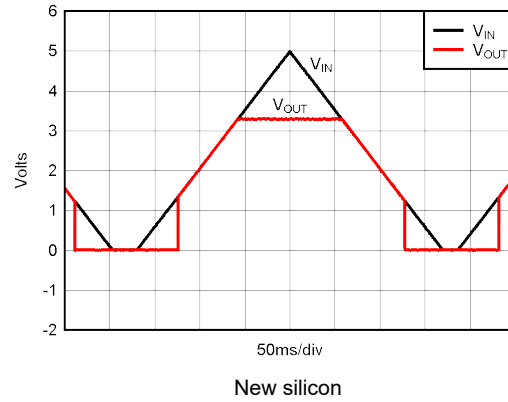


Figure 5-44. TPS73633 Power-Up, Power-Down

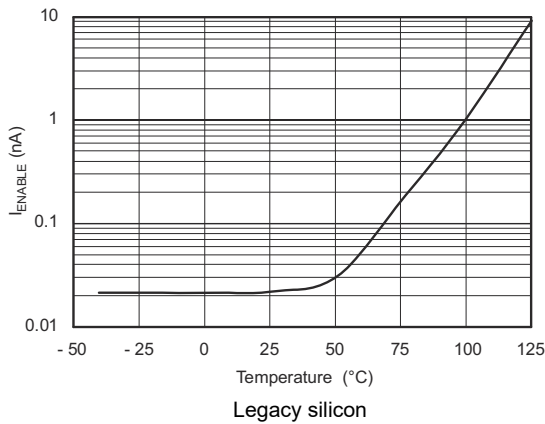


Figure 5-45. I_{ENABLE} vs Temperature

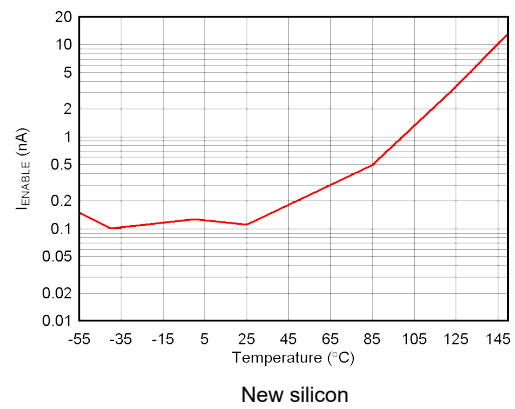


Figure 5-46. I_{ENABLE} vs Temperature

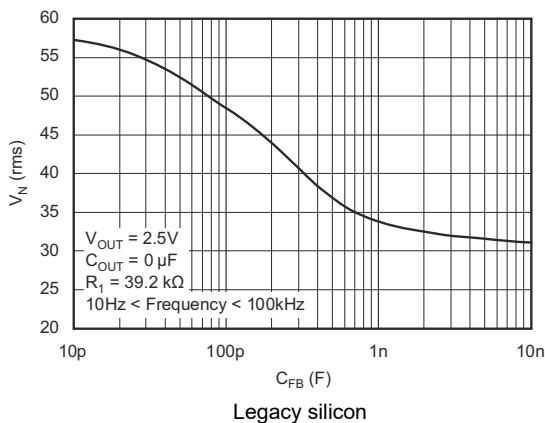


Figure 5-47. TPS73601 RMS Noise Voltage vs C_{FB}

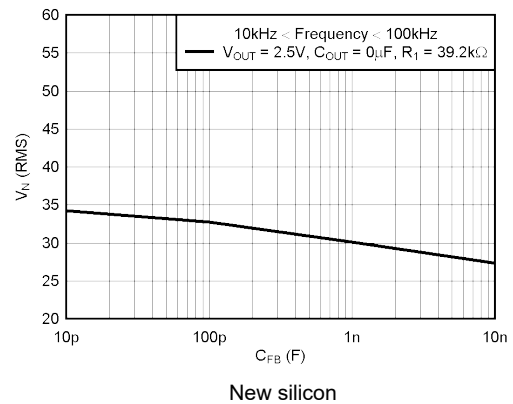


Figure 5-48. TPS73601 RMS Noise Voltage vs C_{FB}

5.7 Typical Characteristics (continued)

For all voltage versions, at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 0.5\text{V}$, $I_{OUT} = 10\text{mA}$, $V_{EN} = 1.7\text{V}$, and $C_{OUT} = 0.1\mu\text{F}$, unless otherwise noted.

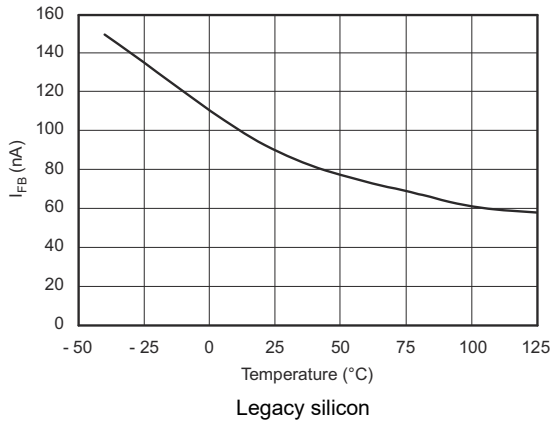


Figure 5-49. TPS73601 I_{FB} vs Temperature

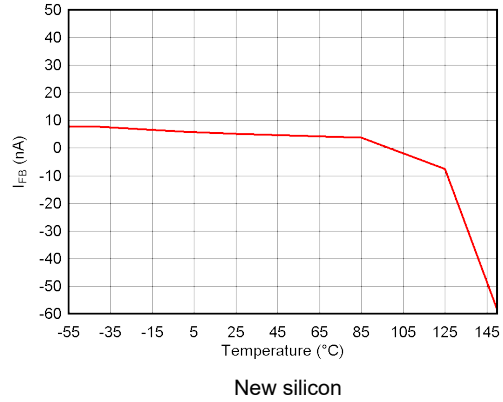


Figure 5-50. TPS73601 I_{FB} vs Temperature

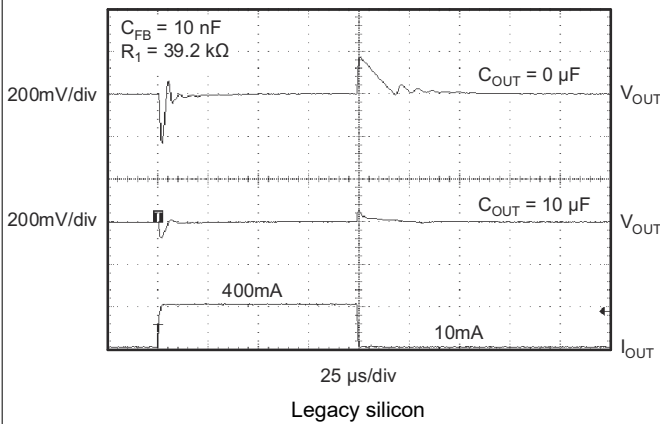


Figure 5-51. TPS73601 Load Transient, Adjustable Version

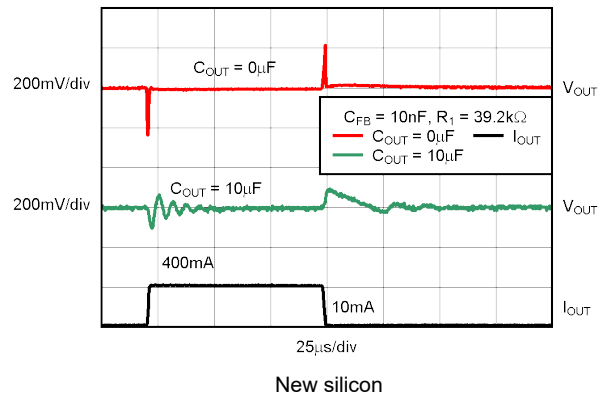


Figure 5-52. TPS73601 Load Transient, Adjustable Version

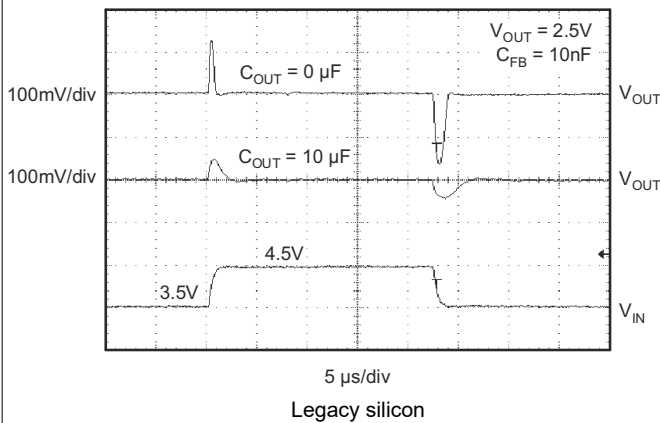


Figure 5-53. TPS73601 Line Transient, Adjustable Version

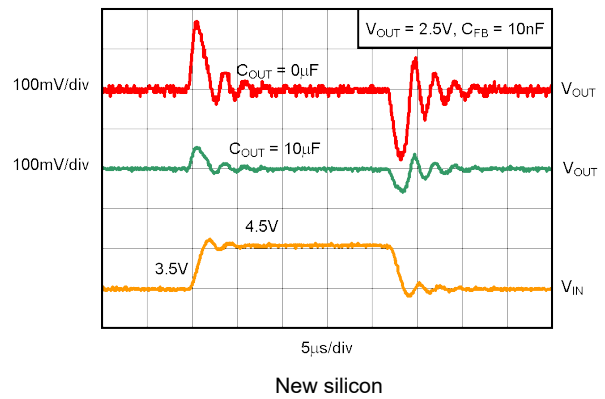


Figure 5-54. TPS73601 Line Transient, Adjustable Version

6 Detailed Description

6.1 Overview

The TPS736 low-dropout linear regulator operates down to an input voltage of 1.7V and supports output voltages down to 1.2V while sourcing up to 400mA of load current. This linear regulator uses an NMOS pass transistor with an integrated 4MHz charge pump to provide a dropout voltage of less than 200mV at full load current. This unique architecture also permits stable regulation over a wide range of output capacitors. In fact, the TPS736 device does not require any output capacitor for stability. The increased insensitivity to the output capacitor value and type makes this linear regulator a good choice when powering a load where the effective capacitance is unknown.

The TPS736 also features a noise reduction (NR) pin that allows for additional reduction of the output noise. With a noise reduction capacitor of 0.01 μ F connected from the NR pin to GND, the TPS736's output noise can be as low as 12.75 μ V_{RMS}. The low noise output featured by the TPS736 makes the device well-suited for powering VCOs or any other noise sensitive load.

6.2 Functional Block Diagrams

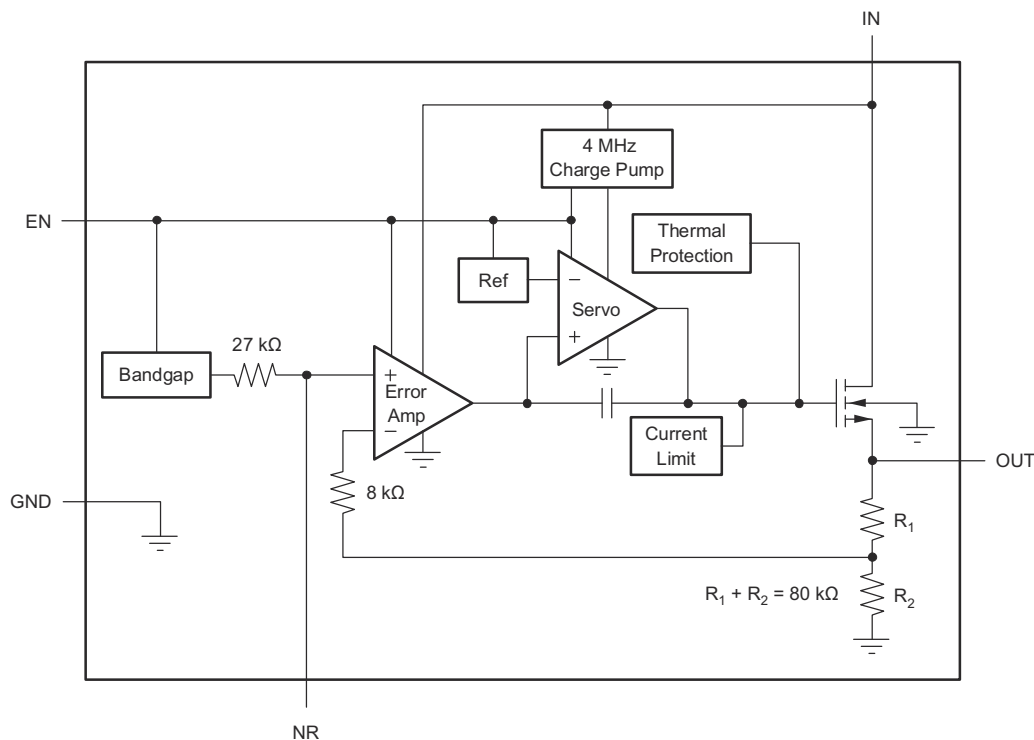
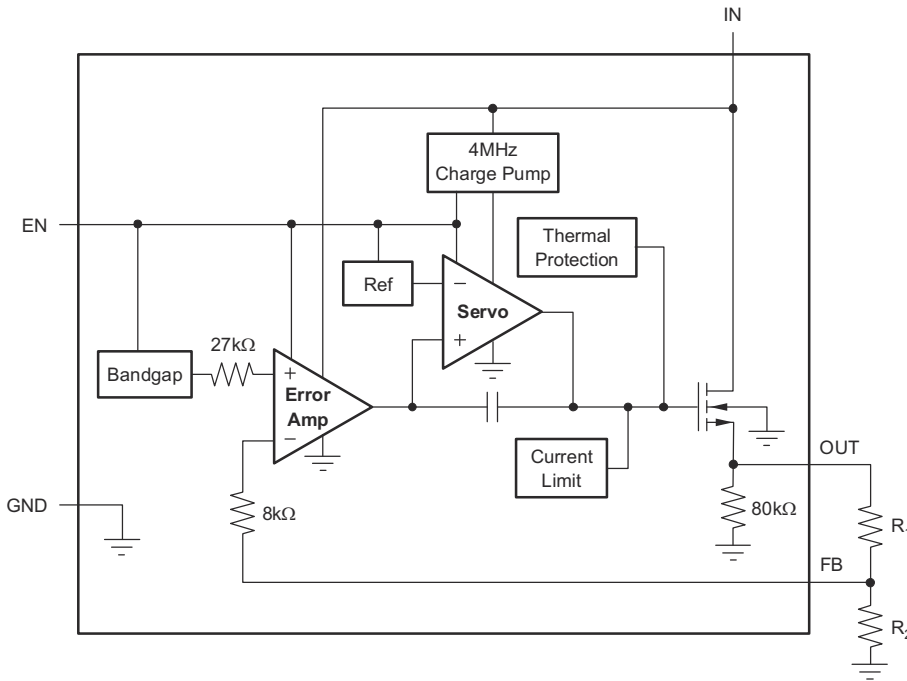


Figure 6-1. Fixed-Voltage Version



Standard 1%
Resistor Values for
Common Output Voltages

V _O	R ₁	R ₂
1.2V	Short	Open
1.5V	23.2kΩ	95.3kΩ
1.8V	28.0kΩ	56.2kΩ
2.5V	39.2kΩ	36.5kΩ
2.8V	44.2kΩ	33.2kΩ
3.0V	46.4kΩ	30.9kΩ
3.3V	52.3kΩ	30.1kΩ

NOTE: $V_{OUT} = (R_1 + R_2)/R_2 \times 1.204$;
 $R_1 || R_2 \cong 19k\Omega$ for best
accuracy.

Figure 6-2. Adjustable-Voltage Version

6.3 Feature Description

6.3.1 Output Noise

A precision band-gap reference is used to generate the internal reference voltage, V_{REF} . This reference is the dominant noise source within the TPS736 and generates approximately $32\mu V_{RMS}$ (10Hz to 100kHz) at the reference output (NR). The regulator control loop gains up the reference noise with the same gain as the reference voltage, so that the noise voltage of the regulator is approximately given by:

$$V_N = 32\mu V_{RMS} \times \frac{(R_1 + R_2)}{R_2} = 32\mu V_{RMS} \times \frac{V_{OUT}}{V_{REF}} \quad (1)$$

Since the value of V_{REF} is 1.2V, this relationship reduces to:

$$V_N(\mu V_{RMS}) = 27 \left(\frac{\mu V_{RMS}}{V} \right) \times V_{OUT}(V) \quad (2)$$

for the case of no C_{NR} .

An internal 27kΩ resistor in series with the noise-reduction pin (NR) forms a low-pass filter for the voltage reference when an external noise-reduction capacitor, C_{NR} , is connected from NR to ground. For $C_{NR} = 10nF$, the total noise in the 10Hz to 100kHz bandwidth is reduced by a factor of approximately 3.2, giving the approximate relationship:

$$V_N(\mu V_{RMS}) = 8.5 \left(\frac{\mu V_{RMS}}{V} \right) \times V_{OUT}(V) \quad (3)$$

for $C_{NR} = 10nF$.

This noise reduction effect is shown as *RMS Noise Voltage vs C_{NR}* in the [Typical Characteristics](#) section.

The TPS73601 adjustable version does not have the NR pin available. However, connecting a feedback capacitor, C_{FB} , from the output to the feedback pin (FB) reduces output noise and improves load transient performance.

The TPS736 uses an internal charge pump to develop an internal supply voltage sufficient to drive the gate of the NMOS pass transistor above V_{OUT} . The charge pump generates approximately 250 μ V of switching noise at approximately 4MHz; however, charge-pump noise contribution is negligible at the output of the regulator for most values of I_{OUT} and C_{OUT} .

6.3.2 Internal Current Limit

The TPS736 internal current limit helps protect the regulator during fault conditions. Foldback current limit helps to protect the regulator from damage during output short-circuit conditions by reducing current limit when V_{OUT} drops below 0.5V. See [Figure 5-17](#) in the *Typical Characteristics* section.

Note from [Figure 5-17](#) that approximately $-0.2V$ of V_{OUT} results in a current limit of 0mA. Therefore, if OUT is forced below $-0.2V$ before EN goes high, the device can not start up. In applications that work with both a positive and negative voltage supply, the TPS736 must be enabled first.

6.3.3 Enable Pin and Shutdown

The enable pin (EN) is active high and is compatible with standard TTL-CMOS levels. V_{EN} below 0.5V (max) turns the regulator off and drops the GND pin current to approximately 10nA. When EN is used to shutdown the regulator, all charge is removed from the pass transistor gate. A V_{EN} above 1.7V (minimum) turns the regulator on and the output ramps back up to a regulated V_{OUT} (see [Figure 5-40](#)).

When shutdown capability is not required, connect EN to V_{IN} . However, the pass transistor cannot be discharged using this configuration, and the pass transistor can be left on (enhanced) for a significant time after V_{IN} has been removed. This scenario can result in reverse current flow (if the IN pin is low impedance) and faster ramp times upon power-up. In addition, for V_{IN} ramp times slower than a few milliseconds, the output can overshoot upon power-up.

Current limit foldback can prevent device start-up under some conditions. See the *Internal Current Limit* section for more information.

6.3.4 Reverse Current

The NMOS pass transistor of the TPS736 provides inherent protection against current flow from the output of the regulator to the input when the gate of the pass transistor is pulled low. To ensure that all charge is removed from the gate of the pass transistor, the EN pin must be driven low before the input voltage is removed. If this is not done, the pass transistor can be left on due to stored charge on the gate.

After the EN pin is driven low, no bias voltage is needed on any pin for reverse current blocking. Reverse current is specified as the current flowing out of the IN pin due to voltage applied on the OUT pin. There is additional current flowing into the OUT pin due to the 80k Ω internal resistor divider to ground (see [Figure 6-1](#) and [Figure 6-2](#)).

For the TPS73601, reverse current can flow when V_{FB} is more than 1.0V above V_{IN} .

6.4 Device Functional Modes

6.4.1 Normal Operation With $1.7V \leq V_{IN} \leq 5.5V$ and $V_{EN} \geq 1.7V$

The TPS736 requires an input voltage of at least 1.7V to function properly and attempt to maintain regulation. If the device output voltage is greater than 1.5V when the input voltage is at 1.7V, the device is operating in dropout and regulation cannot be maintained. Because of the NMOS architecture used in the TPS736, the dropout voltage is not a strong function of the input voltage.

When operating the device near 5.5V, take care to suppress any transient spikes that can exceed the 6.0V absolute maximum voltage rating. The device must never operate at a dc voltage greater than 5.5V.

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

The TPS736 is an LDO regulator that uses an NMOS pass transistor to achieve ultra-low-dropout performance, reverse current blockage, and freedom from output capacitor constraints. These features, combined with low noise and an enable input, make the TPS736 designed for portable applications. This regulator offers a wide selection of fixed output voltage versions and an adjustable output version. All versions have thermal and over-current protection, including foldback current limit.

7.2 Typical Application

Figure 7-1 shows the basic circuit connections for the fixed voltage models. Figure 7-2 gives the connections for the adjustable output version (TPS73601).

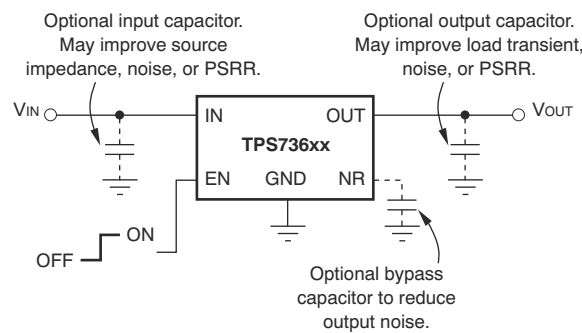


Figure 7-1. Typical Application Circuit for Fixed-Voltage Versions

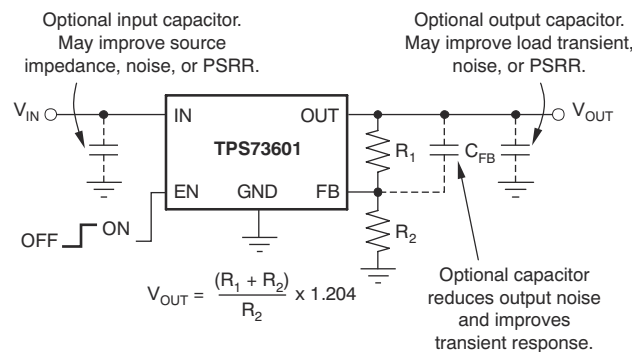


Figure 7-2. Typical Application Circuit for Adjustable-Voltage Version

7.2.1 Design Requirements

For this design example, use the parameters listed below as the input parameters.

Table 7-1. Design Parameters (Fixed-Voltage Version)

PARAMETER	DESIGN REQUIREMENT
Input voltage	5V, $\pm 3\%$
Output voltage	3.3V, $\pm 1\%$
Output current	400mA (maximum), 20mA (minimum)
RMS noise, 10Hz to 100kHz	$< 30\mu\text{V}_{\text{RMS}}$
Ambient temperature	55°C (maximum)

Table 7-2. Design Parameters (Adjustable-Voltage Version)

PARAMETER	DESIGN REQUIREMENT
Input voltage	5V, $\pm 3\%$, provided by the dc/dc converter switching at 1MHz
Output voltage	2.5V, $\pm 1\%$
Output current	0.4A (maximum), 10mA (minimum)
RMS noise, 10Hz to 100kHz	$< 35\mu\text{V}_{\text{RMS}}$
Ambient temperature	55°C (maximum)

7.2.2 Detailed Design Procedure

The first step when designing with a linear regulator is to examine the maximum load current along with the input and output voltage requirements to determine if the device thermal and dropout voltage requirements can be met. At 0.4A, the dropout voltage of the TPS73633 is a maximum of 200mV over temperature; thus, the dropout headroom is sufficient for operation over both input and output voltage accuracy.

The maximum power dissipated in the linear regulator is the maximum voltage dropped across the pass transistor from the input to the output times the maximum load current. In this example, the maximum voltage drop across in the pass transistor is 5V + 3% (5.15V) minus 3.3V – 1% (3.267V) or 1.883V. The power dissipated in the pass transistor is calculated by taking this voltage drop multiplied by the maximum load current. For this example, the maximum power dissipated in the linear regulator is 942mW. Once the power dissipated in the linear regulator is known, the corresponding junction temperature rise can be calculated. To calculate the junction temperature rise above ambient, the power dissipated must be multiplied by the junction-to-ambient thermal resistance. For thermal resistance information see the [Thermal Protection](#) section. For this example, using the DRB package, the maximum junction temperature rise is calculated to be 45°C. The maximum junction temperature rise is calculated by adding junction temperature rise to the maximum ambient temperature. In this example, the maximum junction temperature is 100°C. Keep in mind the maximum junction temperature must be below 125°C for reliable operation. Addition ground planes, added thermal vias, and air flow all help to lower the maximum junction temperature. Using the DCQ or DBV packages are not recommended for this application due to the excessive junction temperature rise that is incurred.

To get the noise level below $30\mu\text{V}_{\text{RMS}}$, a noise reduction capacitance (C_{NR}) of 10nF is selected along with an output capacitance of 10 μF . Referencing the [Output Noise](#) section, the RMS noise can be calculated to be $28\mu\text{V}_{\text{RMS}}$.

Use of an input capacitor is optional. However, in systems where the input supply is located several inches away from the LDO, a small 0.1 μF input capacitor is recommended to negate the adverse effects that input supply inductance has on stability and ac performance.

In the same way as with designing with a fixed output voltage, the first step is to examine the maximum load current along with the input and output voltage requirements to determine if the device thermal and dropout voltage requirements are met. At 0.4A, the maximum dropout voltage is 200mV. Since the input voltage is 5V and the output voltage is 2.5V, there is more than sufficient voltage headroom to avoid dropout and maintain good PSRR.

The maximum power dissipated in the linear regulator is the maximum voltage dropped across the pass transistor from the input to the output times the maximum load current. In this example, the maximum voltage drop across in the pass transistor is $5V + 3\%$ (5.15 V) minus $2.5V - 1\%$ (2.475V) or 2.675V. The power dissipated in the pass transistor is calculated by taking this voltage drop multiplied by the maximum load current. For this example, the maximum power dissipated in the linear regulator is 1.07W. Once the power dissipated in the linear regulator is known, the corresponding junction temperature rise can be calculated. To calculate the junction temperature rise above ambient, the power dissipated must be multiplied by the junction-to-ambient thermal resistance. For thermal resistance information, see the [Thermal Information](#) table. For this example, using the DRB package, the maximum junction temperature rise is calculated to be 51°C. The maximum junction temperature rise is calculated by adding junction temperature rise to the maximum ambient temperature. In this example, the maximum junction temperature is 106°C. Keep in mind the maximum junction temperature must be below 125°C for reliable operation. Addition ground planes, added thermal vias, and air flow all help to lower the maximum junction temperature. Using the DCQ or DBV packages are not recommended for this application due to the excessive junction temperature rise that is incurred.

R_1 and R_2 can be calculated for any output voltage using the formula shown in [Figure 7-2](#). Sample resistor values for common output voltages are shown in [Figure 6-2](#).

For best accuracy, make the parallel combination of R_1 and R_2 approximately equal to 19kΩ. This 19kΩ, in addition to the internal 8kΩ resistor, presents the same impedance to the error amplifier as the 27kΩ bandgap reference output. This impedance helps compensate for leakages into the error amplifier terminals.

Using the values in [Figure 6-2](#) for a 2.5V output results in a value of 39.2kΩ for R_1 and 36.5kΩ for R_2 .

To get the noise level below $35\mu V_{RMS}$, a noise reduction capacitance (C_{FF}) of 10nF is selected. [Figure 5-47](#) must be used as a reference when selecting optimal value for C_{FF} .

A 10μF, low equivalent series resistance (ESR) ceramic X5R capacitor was used on the output of this design to minimize the output voltage droop during a low transient. Use of an input capacitor is optional. However, in systems where the input supply is located several inches away from the LDO, a small 0.1μF input capacitor is recommended to negate the adverse effects that input supply inductance has on stability and ac performance. See the [Input and Output Capacitor Requirements](#) section for additional information about input and output capacitor selection.

7.2.2.1 Input and Output Capacitor Requirements

Although an input capacitor is not required for stability, good analog design practice is to connect a 0.1μF to 1μF, low ESR capacitor across the input supply near the regulator. This capacitor counteracts reactive input sources and improves transient response, noise rejection, and ripple rejection. A higher-value capacitor can be necessary if large, fast rise-time load transients are anticipated or the device is located several inches from the power source.

The TPS736 does not require an output capacitor for stability and has maximum phase margin with no capacitor. The device is designed to be stable for all available types and values of capacitors. In applications where multiple low ESR capacitors are in parallel, ringing can occur when the product of C_{OUT} and total ESR drops below $50n\Omega \times F$. Total ESR includes all parasitic resistances, including capacitor ESR and board, socket, and solder joint resistance. In most applications, the sum of capacitor ESR and trace resistance meets this requirement.

7.2.2.2 Dropout Voltage

The TPS736 uses an NMOS pass transistor to achieve extremely low dropout. When $(V_{IN} - V_{OUT})$ is less than the dropout voltage (V_{DO}), the NMOS pass transistor is in the linear region of operation and the input-to-output resistance is the $R_{DS(on)}$ of the NMOS pass transistor.

For large step changes in load current, the TPS736 requires a larger voltage drop from V_{IN} to V_{OUT} to avoid degraded transient response. The boundary of this transient dropout region is approximately twice the dc dropout. Values of $V_{IN} - V_{OUT}$ above this line provide normal transient response.

Operating in the transient dropout region can cause an increase in recovery time. The time required to recover from a load transient is a function of the magnitude of the change in load current rate, the rate of change in load current, and the available headroom (V_{IN} to V_{OUT} voltage drop). Under worst-case conditions [full-scale instantaneous load change with $(V_{IN} - V_{OUT})$ close to dc dropout levels], the TPS736 can take a couple of hundred microseconds to return to the specified regulation accuracy.

7.2.2.3 Transient Response

The low open-loop output impedance provided by the NMOS pass transistor in a voltage follower configuration allows operation without an output capacitor for many applications. As with any regulator, the addition of a capacitor (nominal value $1\mu\text{F}$) from the OUT pin to ground reduces undershoot magnitude but increases the duration. In the adjustable version, the addition of a capacitor, C_{FB} , from the OUT pin to the FB pin also improves the transient response.

The TPS736 does not have active pull-down when the output is over-voltage. This feature allows applications that connect higher voltage sources, such as alternate power supplies, to the output. This feature also results in an output overshoot of several percent if load current quickly drops to zero when a capacitor is connected to the output. The duration of overshoot can be reduced by adding a load resistor. The overshoot decays at a rate determined by output capacitor C_{OUT} and the internal/external load resistance. The rate of decay is given by:

Fixed voltage version

$$dV / dt = \frac{V_{OUT}}{C_{OUT} \times 80 \text{ k}\Omega \parallel R_{LOAD}} \quad (4)$$

Adjustable voltage version

$$dV / dt = \frac{V_{OUT}}{C_{OUT} \times 80 \text{ k}\Omega \parallel (R_1 + R_2) \parallel R_{LOAD}} \quad (5)$$

7.2.3 Application Curves

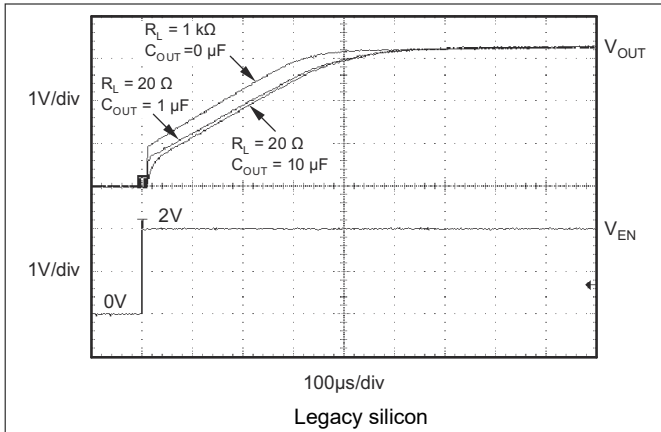


Figure 7-3. TPS73633 Turn-On Response

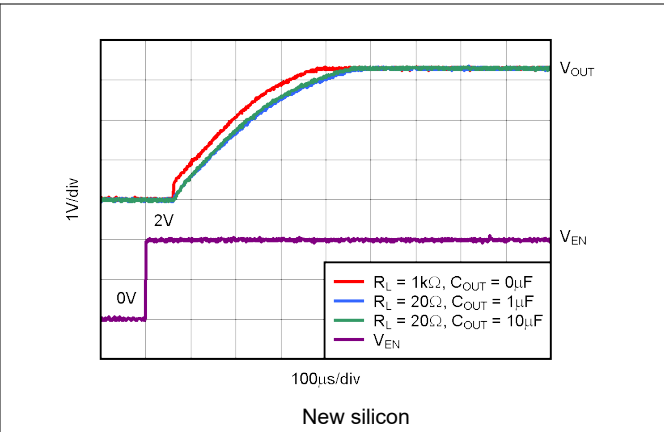


Figure 7-4. TPS73633 Turn-On Response

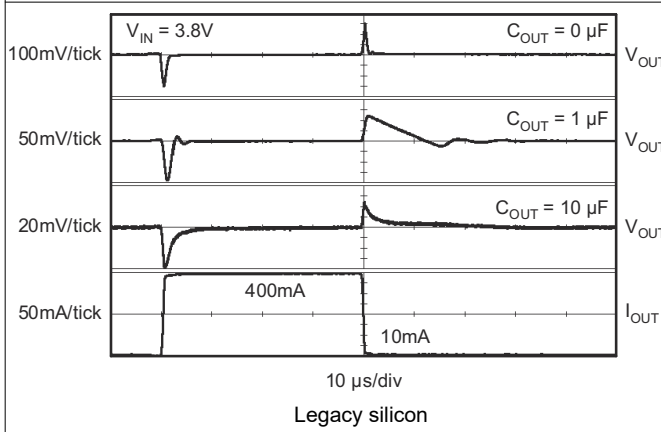


Figure 7-5. TPS73633 Load Transient Response

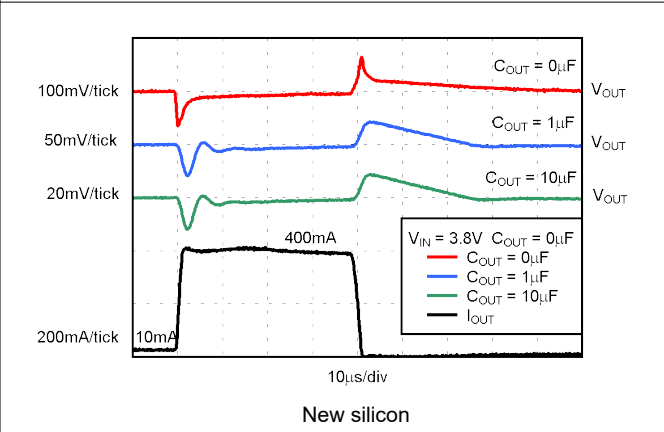


Figure 7-6. TPS73633 Load Transient Response

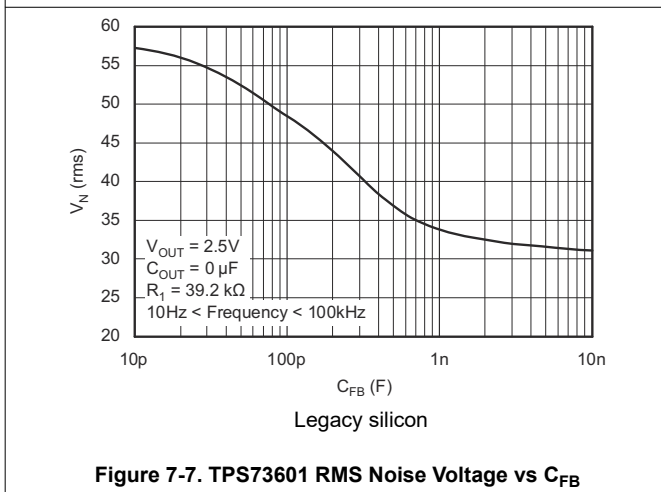


Figure 7-7. TPS73601 RMS Noise Voltage vs C_{FB}

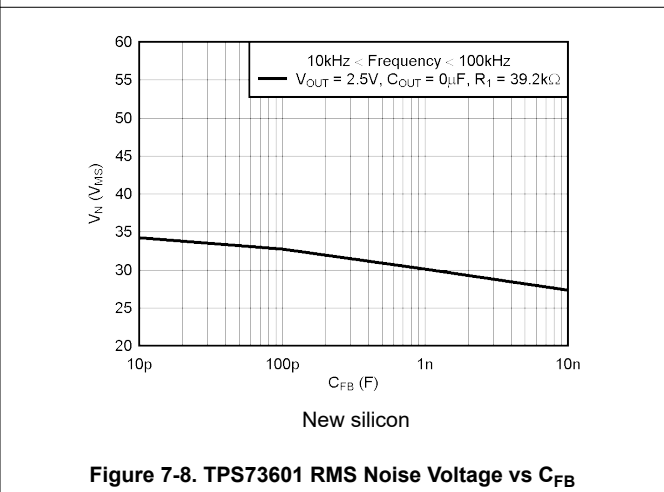


Figure 7-8. TPS73601 RMS Noise Voltage vs C_{FB}

7.2.3 Application Curves (continued)

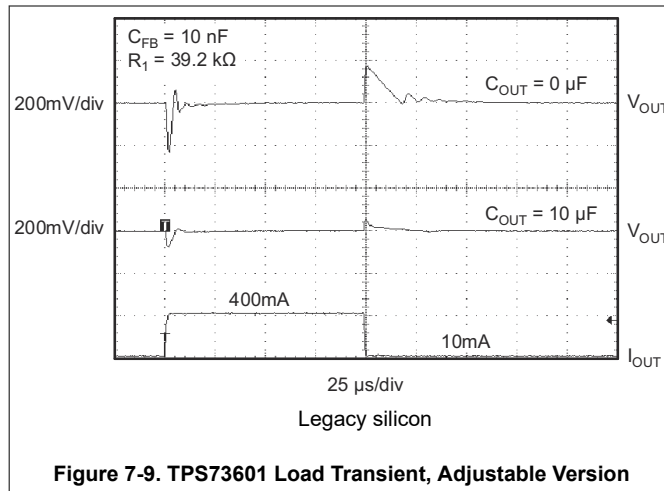


Figure 7-9. TPS73601 Load Transient, Adjustable Version

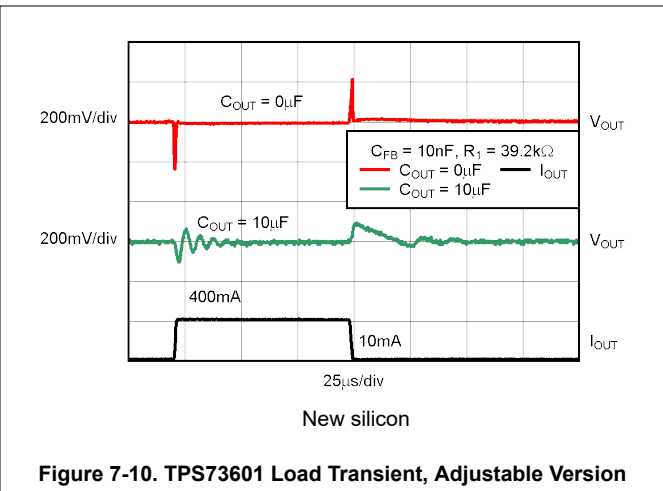


Figure 7-10. TPS73601 Load Transient, Adjustable Version

7.3 Power Supply Recommendations

This device is designed to operate with an input supply range of 1.7V to 5.5V. If the input supply is noisy, additional input capacitors with low ESR help improve output noise performance.

7.4 Layout

7.4.1 Layout Guidelines

To improve ac performance such as PSRR, output noise, and transient response, design the board with ground plane connections for V_{IN} and V_{OUT} capacitors, and the ground plane connected at the GND pin of the device. In addition, the ground connection for the bypass capacitor must connect directly to the GND pin of the device.

7.4.1.1 Power Dissipation

The ability to remove heat from the die is different for each package type, presenting different considerations in the PCB layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Performance data for JEDEC low- and high-K boards are shown in the [Thermal Information](#) table. Using heavier copper increases the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers also improves the heat-sink effectiveness.

Power dissipation depends on input voltage and load conditions. Power dissipation (P_D) is equal to the product of the output current times the voltage drop across the output pass transistor (V_{IN} to V_{OUT}):

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (6)$$

Power dissipation can be minimized by using the lowest possible input voltage necessary to provide the required output voltage.

7.4.1.2 Thermal Protection

Thermal protection disables the output when the junction temperature rises to approximately 160°C, allowing the device to cool. When the junction temperature cools to approximately 140°C, the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit can cycle on and off. This limits the dissipation of the regulator, protecting the device from damage due to overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heat sink. For reliable operation, junction temperature must be limited to 125°C maximum. To estimate the margin of safety in a complete design (including heat sink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection must trigger at least 35°C above the maximum expected ambient condition of your application. This produces a worst-case junction temperature of 125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS736 has been designed to protect against overload conditions. This circuitry is not intended to replace proper heat sinking. Continuously running the TPS736 into thermal shutdown degrades device reliability.

7.4.2 Layout Examples

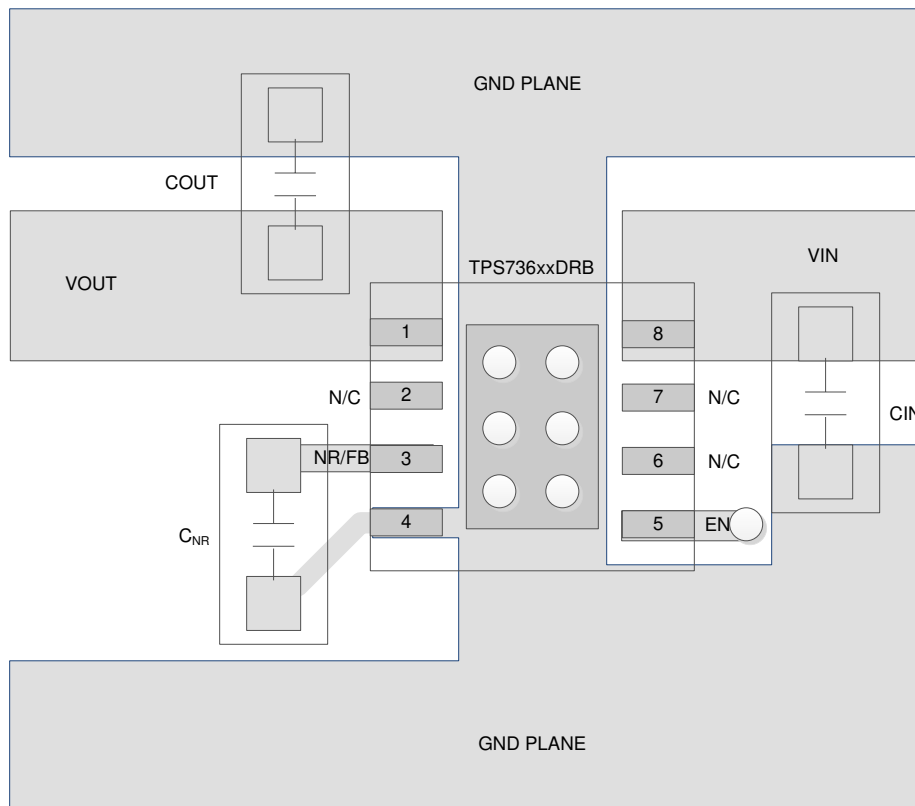


Figure 7-11. Fixed Output Voltage Option Layout (DRB Package)

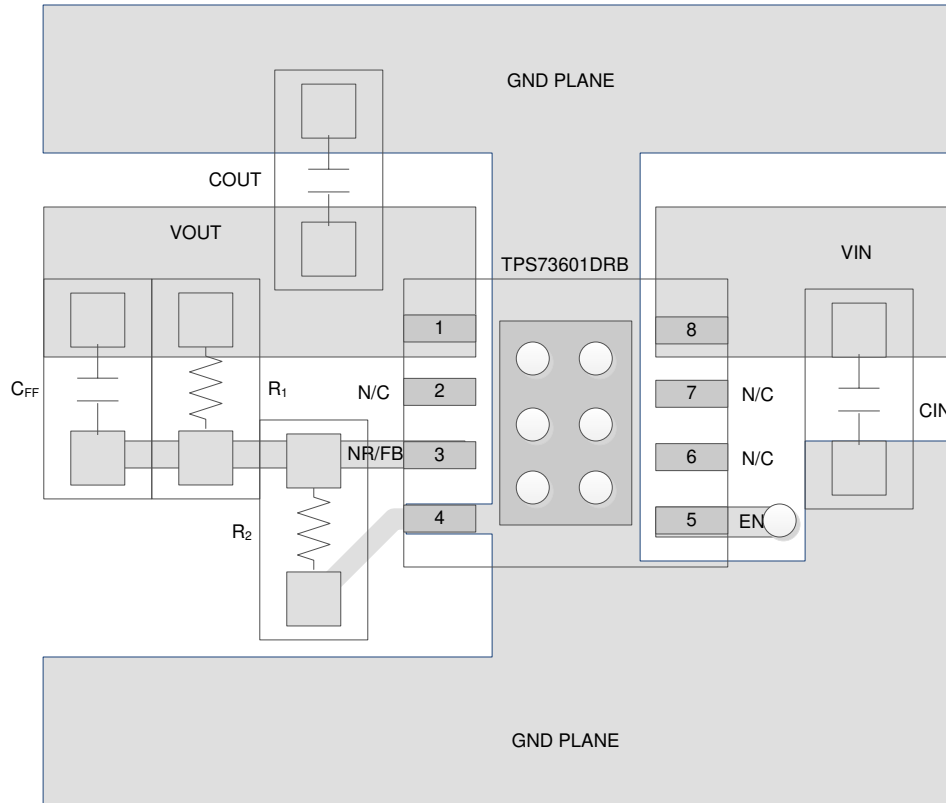


Figure 7-12. Adjustable Output Voltage Option Layout (DRB Package)

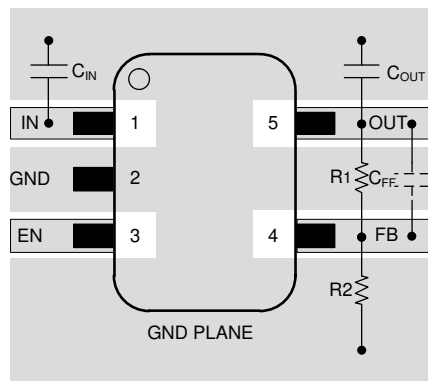


Figure 7-13. Layout Example for the DBV Package Adjustable Version

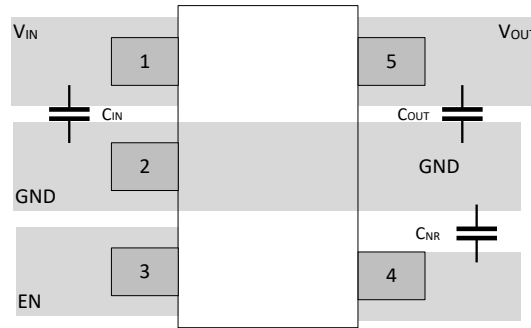


Figure 7-14. Layout Example for the DBV Package Fixed Version

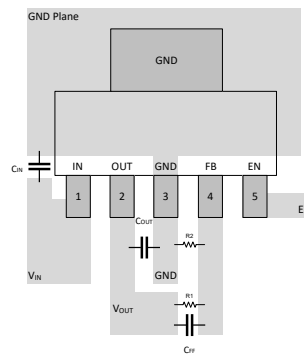


Figure 7-15. Layout Example for the DCQ Package Adjustable Version

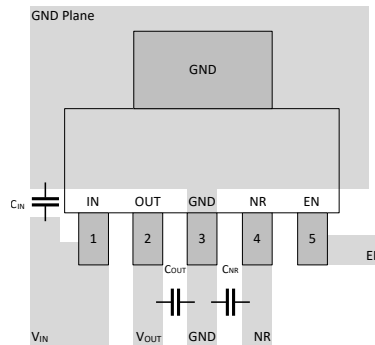


Figure 7-16. Layout Example for the DCQ Package Fixed Version

8 Device and Documentation Support

8.1 Device Support

8.1.1 Development Support

8.1.1.1 Evaluation Modules

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TPS736. The [TPS73601DRBEVM-518 evaluation module](#) (and [related user guide](#)) can be requested at the Texas Instruments website through the product folders or purchased directly from the [TI eStore](#).

8.1.1.2 Spice Models

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. A SPICE model for the TPS736 is available through the product folders under *Simulation Models*.

8.1.2 Device Nomenclature

Table 8-1. Device Nomenclature

PRODUCT ⁽¹⁾	DESCRIPTION
TPS736xxyyy z(M3)	<p>xx is the nominal output voltage (for example, 25 = 2.5V; 01 = Adjustable).</p> <p>yyy is the package designator.</p> <p>z is the package quantity.</p> <p>M3 is a suffix designator for devices that only use the latest manufacturing flow (CSO: RFB). Devices without this suffix ship with the <i>legacy silicon</i> (CSO: DLN) or the <i>new silicon</i> (CSO: RFB). The reel packaging label provides CSO information to distinguish which silicon is being used. Device performance for new and legacy silicon is denoted throughout the document.</p>

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

8.2 Documentation Support

8.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [Regulating \$V_{OUT}\$ Below 1.2V Using an External Reference application note](#)
- Texas Instruments, [TPS73x01DRBEVM-518 user's guide](#)

8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.4 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

8.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

8.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.7 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision W (May 2025) to Revision X (May 2025)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Added new silicon ground pin current spec.....	6

Changes from Revision V (September 2024) to Revision W (May 2025)	Page
• Updated DRB (VSON) for DRB0008A package outline.....	4
• Added new silicon DBV thermals.....	4
• Changed discussion of EN and added information about EN turning the regulator on in <i>Enable Pin and Shutdown</i> section.....	18
• Deleted <i>Package Mounting</i> section.....	25
• Changed <i>legacy chip</i> to <i>legacy silicon</i> in <i>Device Nomenclature</i> table.....	28

Changes from Revision U (January 2015) to Revision V (September 2024)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Added M3 devices to document and added the M3 new silicon <i>Thermal Information</i> table.....	1
• Changed max output current.....	4
• Changed VFB typical value.....	6
• Added new silicon current limit.....	6
• Added new silicon plots to <i>Typical Characteristics</i> section.....	7
• Changed <i>Output current</i> value from 500mA to 400mA in <i>Design Parameters (Fixed-Voltage Version)</i> table..	20
• Changed <i>Detailed Design Procedure</i> section: Changed dropout voltage value from 0.5A to 0.4A, changed maximum dropout voltage from an estimation to 200mV	20
• Added new silicon plots to <i>Application Curves</i> section.....	23
• Added <i>Layout Example for the DBV Package Adjustable Version</i> through <i>Layout Example for the DCQ Package Fixed Version</i> figures to <i>Layout Examples</i> section.....	25
• Added M3 information to <i>Device Nomenclature</i> section.....	28

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS73601DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DBVR1G4	NRND	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DBVR1G4.A	NRND	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DBVRM3	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DBVTG4	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DBVTG4.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DCQ	Obsolete	Production	SOT-223 (DCQ) 6	-	-	Call TI	Call TI	-40 to 125	PS73601
TPS73601DCQG4	Obsolete	Production	SOT-223 (DCQ) 6	-	-	Call TI	Call TI	-40 to 125	PS73601
TPS73601DCQR	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS73601
TPS73601DCQR.A	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS73601
TPS73601DRBR	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DRBR.A	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DRBRG4	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DRBRM3	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DRBRM3.A	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DRBT	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DRBT.A	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS73601DRBTG4	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PJFQ
TPS736125DRBR	NRND	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	T49
TPS736125DRBR.A	NRND	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T49
TPS73615DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T44
TPS73615DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T44
TPS73615DBVT	Obsolete	Production	SOT-23 (DBV) 5	-	-	Call TI	Call TI	-40 to 125	T44
TPS73615DCQ	Obsolete	Production	SOT-223 (DCQ) 6	-	-	Call TI	Call TI	-40 to 125	PS73615
TPS73615DCQR	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	PS73615
TPS73615DCQR.A	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	PS73615

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS73615DCQRG4	NRND	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS73615
TPS73615DCQRG4.A	NRND	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS73615
TPS73615DRBR	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T44
TPS73615DRBR.A	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T44
TPS73616DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OCQ
TPS73616DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OCQ
TPS73616DBVT	Obsolete	Production	SOT-23 (DBV) 5	-	-	Call TI	Call TI	-40 to 125	OCQ
TPS73618DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T43
TPS73618DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T43
TPS73618DBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T43
TPS73618DBVRG4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T43
TPS73618DBVRM3	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	T43
TPS73618DBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T43
TPS73618DBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T43
TPS73618DBVTG4	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T43
TPS73618DBVTG4.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T43
TPS73618DCQR	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	PS73618
TPS73618DCQR.A	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	PS73618
TPS73619DRBR	NRND	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	BYY
TPS73619DRBR.A	NRND	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	BYY
TPS73619DRBT	Obsolete	Production	SON (DRB) 8	-	-	Call TI	Call TI	-40 to 125	BYY
TPS73625DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T42
TPS73625DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T42
TPS73625DBVRG4	NRND	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T42
TPS73625DBVRG4.A	NRND	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T42
TPS73625DBVRM3	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	T42
TPS73625DBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T42
TPS73625DBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T42
TPS73625DBVTG4	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T42
TPS73625DBVTG4.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T42
TPS73625DCQ	Obsolete	Production	SOT-223 (DCQ) 6	-	-	Call TI	Call TI	-40 to 125	PS73625

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS73625DCQR	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	PS73625
TPS73625DCQR.A	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	PS73625
TPS73630DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T45
TPS73630DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T45
TPS73630DBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T45
TPS73630DBVRG4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T45
TPS73630DBVRM3	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	T45
TPS73630DBVT	Obsolete	Production	SOT-23 (DBV) 5	-	-	Call TI	Call TI	-40 to 125	T45
TPS73630DCQ	Obsolete	Production	SOT-223 (DCQ) 6	-	-	Call TI	Call TI	-40 to 125	PS73630
TPS73630DCQR	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS73630
TPS73630DCQR.A	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS73630
TPS73632DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T53
TPS73632DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T53
TPS73632DBVRG4	NRND	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T53
TPS73632DBVRG4.A	NRND	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T53
TPS73633DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DBVR1G4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DBVR1G4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DBVRM3	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DBVTG4	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DBVTG4.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DCQ	Obsolete	Production	SOT-223 (DCQ) 6	-	-	Call TI	Call TI	-40 to 125	PS73633
TPS73633DCQR	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS73633
TPS73633DCQR.A	Active	Production	SOT-223 (DCQ) 6	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS73633
TPS73633DRBR	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T46
TPS73633DRBR.A	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T46
TPS73633DRBRM3	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DRBRM3.A	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS73633DRBT	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DRBT.A	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73633DRBTG4	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T46
TPS73643DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T54
TPS73643DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T54
TPS73643DBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T54

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF TPS736 :

- Automotive : [TPS736-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS73601DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73601DBVR1G4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73601DBVRM3	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS73601DBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TPS73601DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TPS73601DCQR	SOT-223	DCQ	6	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
TPS73601DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS73601DRBRM3	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS73601DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS736125DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS73615DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TPS73615DCQR	SOT-223	DCQ	6	2500	330.0	12.4	6.85	7.3	1.88	8.0	12.0	Q3
TPS73615DCQRG4	SOT-223	DCQ	6	2500	330.0	12.4	7.1	7.45	1.88	8.0	12.0	Q3
TPS73615DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS73616DBVR	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS73618DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS73618DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73618DBVRM3	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS73618DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73618DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73618DCQR	SOT-223	DCQ	6	2500	330.0	12.4	6.85	7.3	1.88	8.0	12.0	Q3
TPS73619DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
TPS73625DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS73625DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73625DBVRG4	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS73625DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73625DBVRM3	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS73625DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73625DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73625DCQR	SOT-223	DCQ	6	2500	330.0	12.4	6.85	7.3	1.88	8.0	12.0	Q3
TPS73630DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73630DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73630DBVRM3	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS73630DCQR	SOT-223	DCQ	6	2500	330.0	12.4	7.1	7.45	1.88	8.0	12.0	Q3
TPS73632DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73632DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73633DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73633DBVR1G4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73633DBVRM3	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS73633DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73633DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS73633DCQR	SOT-223	DCQ	6	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
TPS73633DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS73633DRBRM3	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS73633DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS73643DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS73601DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73601DBVR1G4	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73601DBVRM3	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS73601DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS73601DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS73601DCQR	SOT-223	DCQ	6	2500	366.0	364.0	50.0
TPS73601DRBR	SON	DRB	8	3000	367.0	367.0	35.0
TPS73601DRBRM3	SON	DRB	8	3000	367.0	367.0	35.0
TPS73601DRBT	SON	DRB	8	250	210.0	185.0	35.0
TPS736125DRBR	SON	DRB	8	3000	353.0	353.0	32.0
TPS73615DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73615DCQR	SOT-223	DCQ	6	2500	356.0	356.0	36.0
TPS73615DCQRG4	SOT-223	DCQ	6	2500	346.0	346.0	29.0
TPS73615DRBR	SON	DRB	8	3000	353.0	353.0	32.0
TPS73616DBVR	SOT-23	DBV	5	3000	200.0	183.0	25.0
TPS73618DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73618DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73618DBVRM3	SOT-23	DBV	5	3000	210.0	185.0	35.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS73618DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS73618DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS73618DCQR	SOT-223	DCQ	6	2500	356.0	356.0	36.0
TPS73619DRBR	SON	DRB	8	3000	367.0	367.0	38.0
TPS73625DBVR	SOT-23	DBV	5	3000	200.0	183.0	25.0
TPS73625DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73625DBVRG4	SOT-23	DBV	5	3000	200.0	183.0	25.0
TPS73625DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73625DBVRM3	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS73625DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS73625DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS73625DCQR	SOT-223	DCQ	6	2500	356.0	356.0	36.0
TPS73630DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73630DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73630DBVRM3	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS73630DCQR	SOT-223	DCQ	6	2500	346.0	346.0	41.0
TPS73632DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73632DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73633DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73633DBVR1G4	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS73633DBVRM3	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS73633DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS73633DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS73633DCQR	SOT-223	DCQ	6	2500	366.0	364.0	50.0
TPS73633DRBR	SON	DRB	8	3000	367.0	367.0	35.0
TPS73633DRBRM3	SON	DRB	8	3000	367.0	367.0	35.0
TPS73633DRBT	SON	DRB	8	250	210.0	185.0	35.0
TPS73643DBVR	SOT-23	DBV	5	3000	200.0	183.0	25.0

DRB 8

GENERIC PACKAGE VIEW

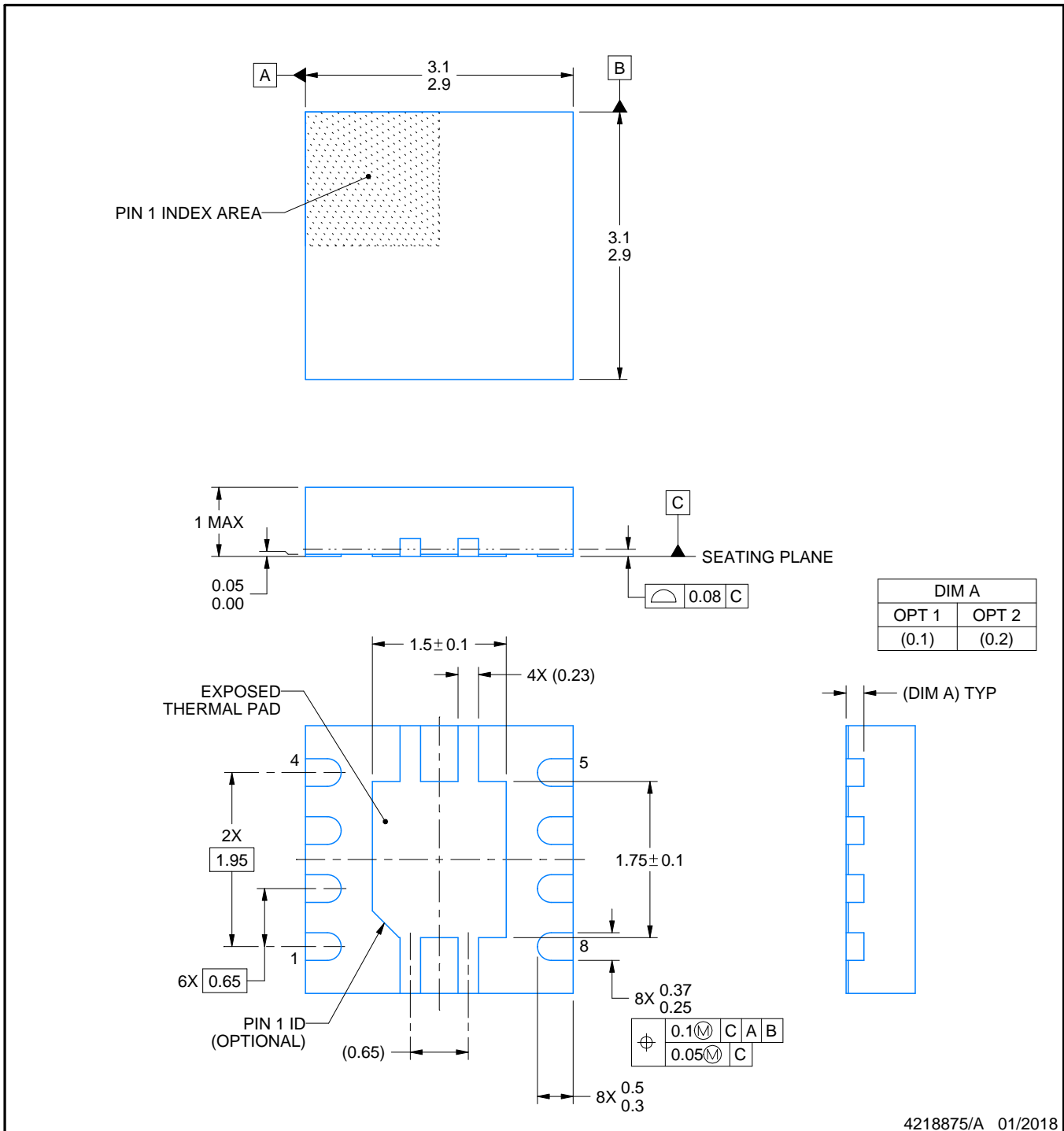
VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4203482/L



4218875/A 01/2018

NOTES:

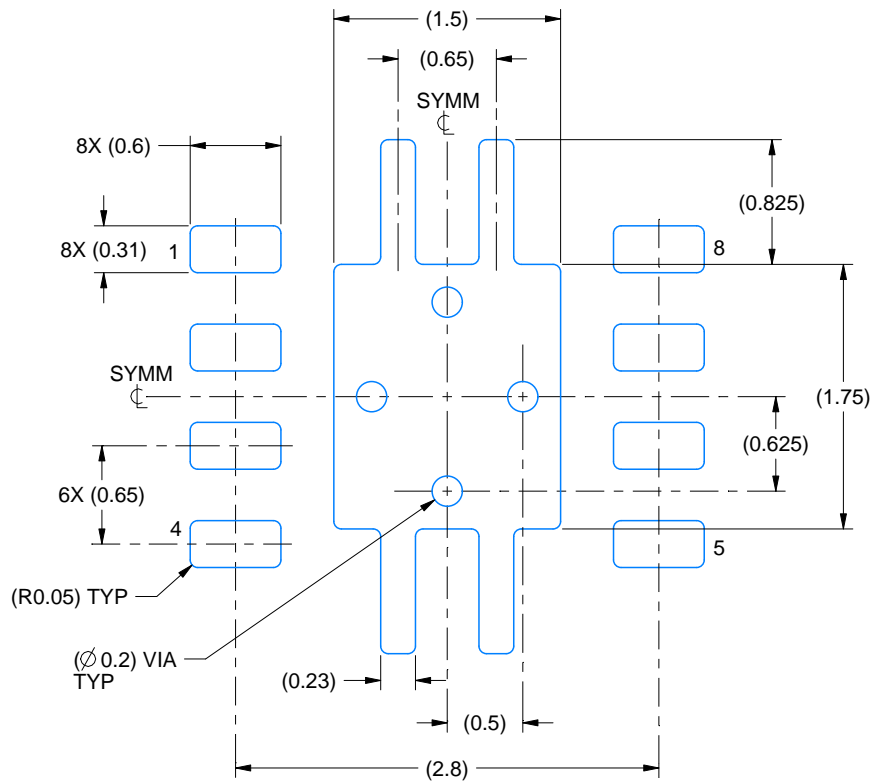
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

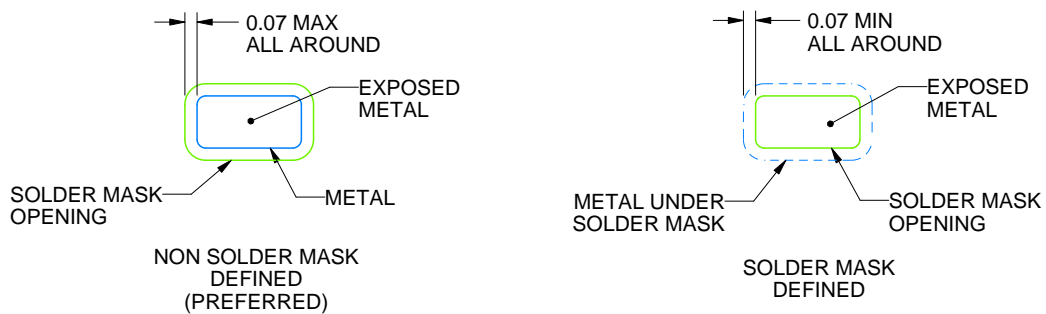
DRB0008A

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X



SOLDER MASK DETAILS

4218875/A 01/2018

NOTES: (continued)

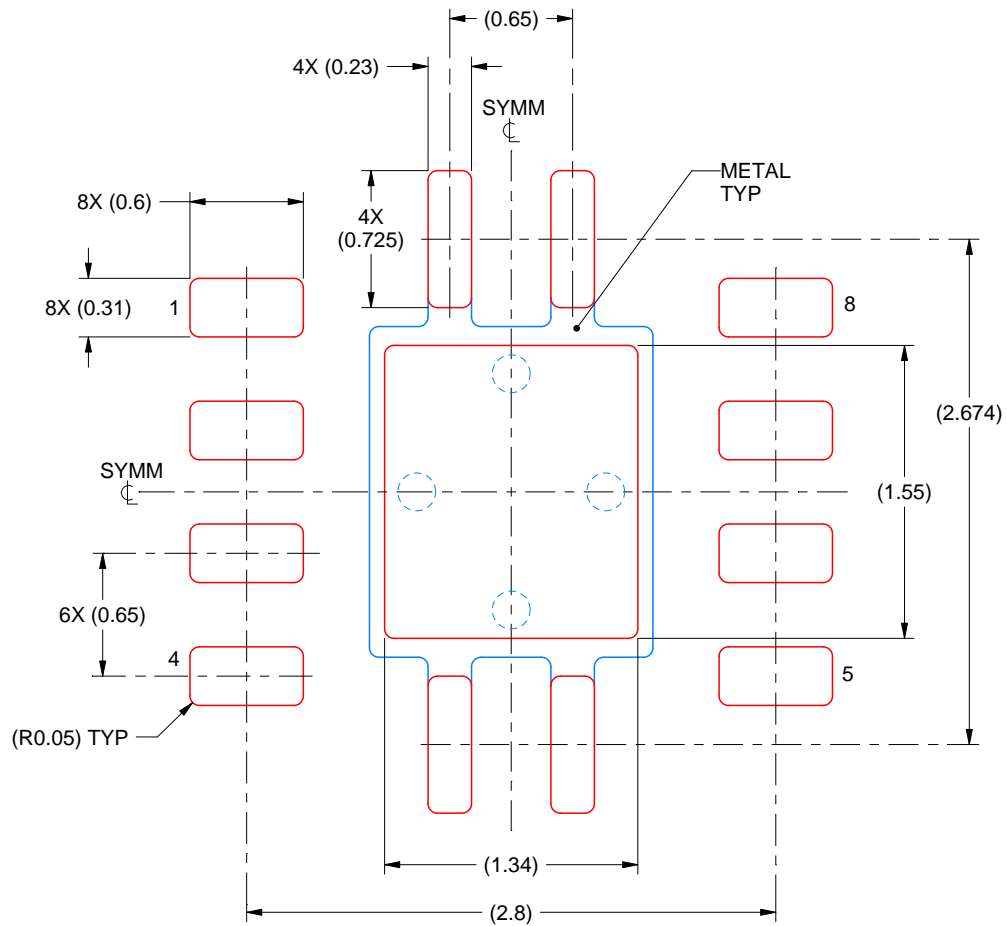
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

DRB0008A

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
84% PRINTED SOLDER COVERAGE BY AREA
SCALE:25X

4218875/A 01/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



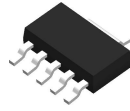
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

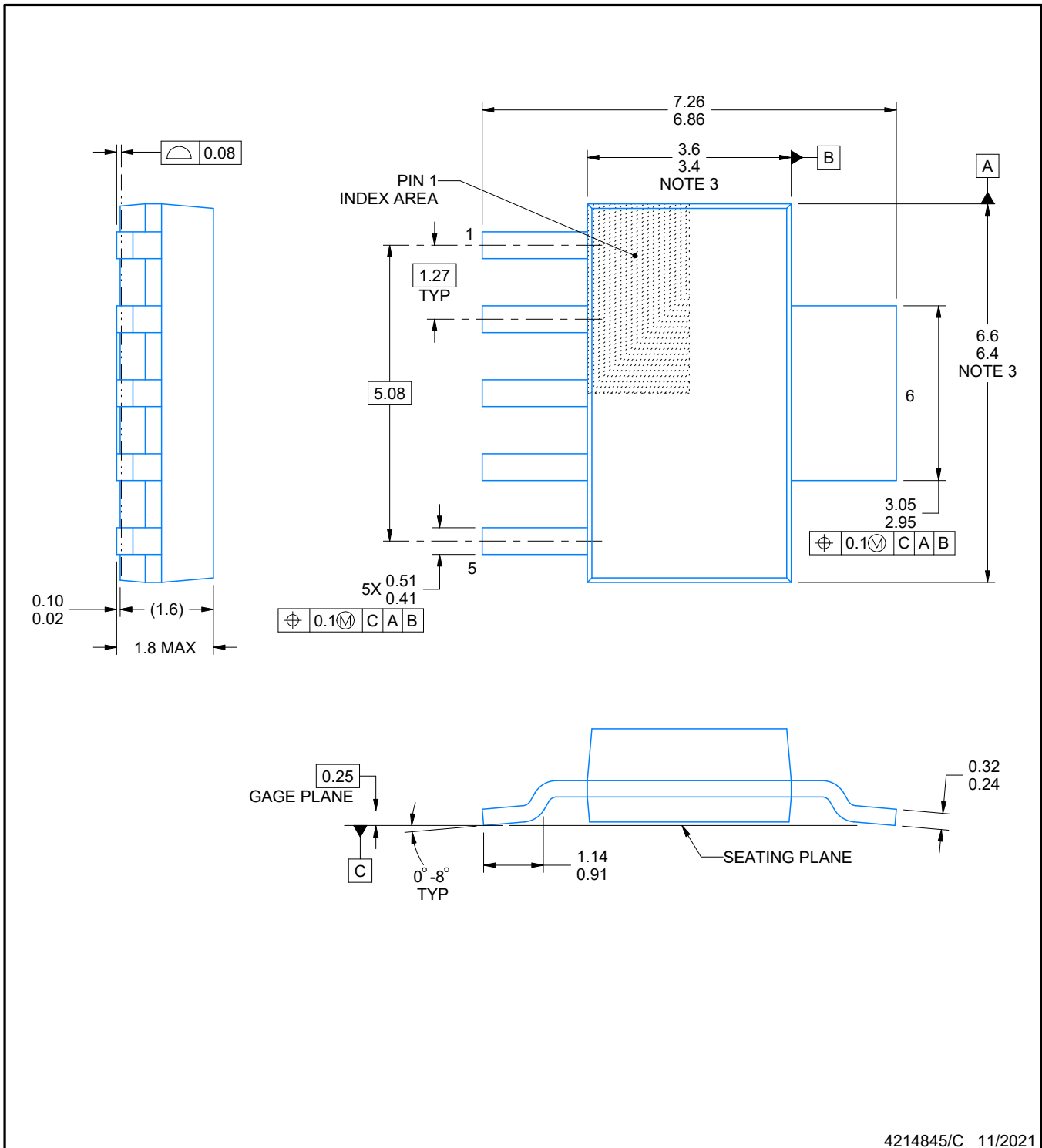
DCQ0006A



PACKAGE OUTLINE

SOT - 1.8 mm max height

PLASTIC SMALL OUTLINE



4214845/C 11/2021

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.

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